

Structured Electronic Design

EE4109

Homework 1

Design of a CS stage,
Design tasks

Anton J.M. Montagne

Tasks

Tasks

1. Design a CS stage that can drive the load
(from 50 Ohm)

Tasks

1. Design a CS stage that can drive the load
(from 50 Ohm)
2. Design a CS stage that can be used as input stage
(antenna length = 18cm, capacitance = 1.5pF)

Tasks

1. Design a CS stage that can drive the load
(from 50 Ohm)
2. Design a CS stage that can be used as input stage
(antenna length = 18cm, capacitance = 1.5pF)

Deliver:

Tasks

1. Design a CS stage that can drive the load
(from 50 Ohm)
2. Design a CS stage that can be used as input stage
(antenna length = 18cm, capacitance = 1.5pF)

Deliver:

SLiCAP generated HTML report with minimum values for the width, the length, the drain-source voltage and the drain current

Tasks

1. Design a CS stage that can drive the load
(from 50 Ohm)
2. Design a CS stage that can be used as input stage
(antenna length = 18cm, capacitance = 1.5pF)

Deliver:

SLiCAP generated HTML report with minimum values for the width, the length, the drain-source voltage and the drain current

Structured Electronic Design

EE4109

Homework 1

Design of a CS stage,
Load drive requirements

Anton J.M. Montagne

Load drive requirements

Load drive requirements

0 dBm in 50 Ohm

Load drive requirements

0 dBm in 50 Ohm

1mW in 50 Ohm

Load drive requirements

0 dBm in 50 Ohm

1mW in 50 Ohm

225mV_{rms} in 50 Ohm

Load drive requirements

0 dBm in 50 Ohm

1mW in 50 Ohm

225mV_{rms} in 50 Ohm

Sinewave: crest factor 1.41: 320mV_p, 6.4mA_p

Load drive requirements

0 dBm in 50 Ohm

1mW in 50 Ohm

225mV_{rms} in 50 Ohm

Sinewave: crest factor 1.41: 320mV_p, 6.4mA_p

Noise: crest factor 3: 675mV, 13.5mA_p

Load drive requirements

0 dBm in 50 Ohm

1mW in 50 Ohm

225mV_{rms} in 50 Ohm

Sinewave: crest factor 1.41: 320mV_p, 6.4mA_p

Noise: crest factor 3: 675mV, 13.5mA_p

Structured Electronic Design

EE4109

Homework 1

Design of a CS stage,
Output stage drive requirements

Anton J.M. Montagne

Output stage drive options

Output stage drive options

No output feedback:

Output stage drive options

No output feedback:

Output impedance of the CS stage has to be 50 Ohm

Output stage drive options

No output feedback:

Output impedance of the CS stage has to be 50 Ohm

Output stage drives 50 Ohm

Output stage drive options

No output feedback:

Output impedance of the CS stage has to be 50 Ohm

Output stage drives 50 Ohm

Sinewave: 320mV_p , 6.4mA_p

Output stage drive options

No output feedback:

Output impedance of the CS stage has to be 50 Ohm

Output stage drives 50 Ohm

Sinewave: 320mV_p, 6.4mA_p

Noise: 675mV_p, 13.5mA_p

Output stage drive options

No output feedback:

Output impedance of the CS stage has to be 50 Ohm

Output stage drives 50 Ohm

Sinewave: 320mV_p, 6.4mA_p

Noise: 675mV_p, 13.5mA_p

Only output voltage feedback:

Output stage drive options

No output feedback:

Output impedance of the CS stage has to be 50 Ohm

Output stage drives 50 Ohm

Sinewave: 320mV_p, 6.4mA_p

Noise: 675mV_p, 13.5mA_p

Only output voltage feedback:

Output impedance of the amplifier approximates zero

Output stage drive options

No output feedback:

Output impedance of the CS stage has to be 50 Ohm
Output stage drives 50 Ohm

Sinewave: 320mV_p , 6.4mA_p

Noise: 675mV_p , 13.5mA_p

Only output voltage feedback:

Output impedance of the amplifier approximates zero

Insert 50 Ohm in series with the output to obtain 50 Ohm

Output stage drive options

No output feedback:

Output impedance of the CS stage has to be 50 Ohm
Output stage drives 50 Ohm

Sinewave: 320mV_p , 6.4mA_p

Noise: 675mV_p , 13.5mA_p

Only output voltage feedback:

Output impedance of the amplifier approximates zero
Insert 50 Ohm in series with the output to obtain 50 Ohm
Output stage drives 100 Ohm with two times the voltage

Output stage drive options

No output feedback:

Output impedance of the CS stage has to be 50 Ohm
Output stage drives 50 Ohm

Sinewave: 320mV_p, 6.4mA_p

Noise: 675mV_p, 13.5mA_p

Only output voltage feedback:

Output impedance of the amplifier approximates zero
Insert 50 Ohm in series with the output to obtain 50 Ohm
Output stage drives 100 Ohm with two times the voltage

Sinewave: 640mV_p, 6.4mA_p

Output stage drive options

No output feedback:

Output impedance of the CS stage has to be 50 Ohm
Output stage drives 50 Ohm

Sinewave: 320mV_p , 6.4mA_p
Noise: 675mV_p , 13.5mA_p

Only output voltage feedback:

Output impedance of the amplifier approximates zero
Insert 50 Ohm in series with the output to obtain 50 Ohm
Output stage drives 100 Ohm with two times the voltage

Sinewave: 640mV_p , 6.4mA_p
Noise: 1.3V_p , 13.5mA_p

Output stage drive options

No output feedback:

Output impedance of the CS stage has to be 50 Ohm
Output stage drives 50 Ohm

Sinewave: 320mV_p , 6.4mA_p
Noise: 675mV_p , 13.5mA_p

Only output voltage feedback:

Output impedance of the amplifier approximates zero
Insert 50 Ohm in series with the output to obtain 50 Ohm
Output stage drives 100 Ohm with two times the voltage
Ignored current drawn by feedback network

Sinewave: 640mV_p , 6.4mA_p
Noise: 1.3V_p , 13.5mA_p

Output stage drive options

No output feedback:

Output impedance of the CS stage has to be 50 Ohm
Output stage drives 50 Ohm

Sinewave: 320mV_p , 6.4mA_p
Noise: 675mV_p , 13.5mA_p

Only output voltage feedback:

Output impedance of the amplifier approximates zero
Insert 50 Ohm in series with the output to obtain 50 Ohm
Output stage drives 100 Ohm with two times the voltage
Ignored current drawn by feedback network

Sinewave: 640mV_p , 6.4mA_p
Noise: 1.3V_p , 13.5mA_p

Output current feedback:

Output stage drive options

No output feedback:

Output impedance of the CS stage has to be 50 Ohm
Output stage drives 50 Ohm

Sinewave: 320mV_p , 6.4mA_p
Noise: 675mV_p , 13.5mA_p

Only output voltage feedback:

Output impedance of the amplifier approximates zero
Insert 50 Ohm in series with the output to obtain 50 Ohm
Output stage drives 100 Ohm with two times the voltage
Ignored current drawn by feedback network

Sinewave: 640mV_p , 6.4mA_p
Noise: 1.3V_p , 13.5mA_p

Output current feedback:

Output impedance of the amplifier approximates infinity

Output stage drive options

No output feedback:

Output impedance of the CS stage has to be 50 Ohm
Output stage drives 50 Ohm

Sinewave: 320mV_p , 6.4mA_p
Noise: 675mV_p , 13.5mA_p

Only output voltage feedback:

Output impedance of the amplifier approximates zero
Insert 50 Ohm in series with the output to obtain 50 Ohm
Output stage drives 100 Ohm with two times the voltage
Ignored current drawn by feedback network

Sinewave: 640mV_p , 6.4mA_p
Noise: 1.3V_p , 13.5mA_p

Output current feedback:

Output impedance of the amplifier approximates infinity
Insert 50 Ohm in parallel with the output to obtain 50 Ohm

Output stage drive options

No output feedback:

Output impedance of the CS stage has to be 50 Ohm
Output stage drives 50 Ohm

Sinewave: 320mV_p , 6.4mA_p
Noise: 675mV_p , 13.5mA_p

Only output voltage feedback:

Output impedance of the amplifier approximates zero
Insert 50 Ohm in series with the output to obtain 50 Ohm
Output stage drives 100 Ohm with two times the voltage
Ignored current drawn by feedback network

Sinewave: 640mV_p , 6.4mA_p
Noise: 1.3V_p , 13.5mA_p

Output current feedback:

Output impedance of the amplifier approximates infinity
Insert 50 Ohm in parallel with the output to obtain 50 Ohm
Output stage drives 25 Ohm with two times the current

Output stage drive options

No output feedback:

Output impedance of the CS stage has to be 50 Ohm
Output stage drives 50 Ohm

Sinewave: 320mV_p, 6.4mA_p
Noise: 675mV_p, 13.5mA_p

Only output voltage feedback:

Output impedance of the amplifier approximates zero
Insert 50 Ohm in series with the output to obtain 50 Ohm
Output stage drives 100 Ohm with two times the voltage
Ignored current drawn by feedback network

Sinewave: 640mV_p, 6.4mA_p
Noise: 1.3V_p, 13.5mA_p

Output current feedback:

Output impedance of the amplifier approximates infinity
Insert 50 Ohm in parallel with the output to obtain 50 Ohm
Output stage drives 25 Ohm with two times the current

Sinewave: 320mV_p, 12.8mA_p

Output stage drive options

No output feedback:

Output impedance of the CS stage has to be 50 Ohm
Output stage drives 50 Ohm

Sinewave: 320mV_p, 6.4mA_p
Noise: 675mV_p, 13.5mA_p

Only output voltage feedback:

Output impedance of the amplifier approximates zero
Insert 50 Ohm in series with the output to obtain 50 Ohm
Output stage drives 100 Ohm with two times the voltage
Ignored current drawn by feedback network

Sinewave: 640mV_p, 6.4mA_p
Noise: 1.3V_p, 13.5mA_p

Output current feedback:

Output impedance of the amplifier approximates infinity
Insert 50 Ohm in parallel with the output to obtain 50 Ohm
Output stage drives 25 Ohm with two times the current

Sinewave: 320mV_p, 12.8mA_p
Noise: 675mV_p, 27mA_p

Output stage drive options

No output feedback:

Output impedance of the CS stage has to be 50 Ohm
Output stage drives 50 Ohm

Sinewave: 320mV_p , 6.4mA_p
Noise: 675mV_p , 13.5mA_p

Only output voltage feedback:

Output impedance of the amplifier approximates zero
Insert 50 Ohm in series with the output to obtain 50 Ohm
Output stage drives 100 Ohm with two times the voltage
Ignored current drawn by feedback network

Sinewave: 640mV_p , 6.4mA_p
Noise: 1.3V_p , 13.5mA_p

Output current feedback:

Output impedance of the amplifier approximates infinity
Insert 50 Ohm in parallel with the output to obtain 50 Ohm
Output stage drives 25 Ohm with two times the current
Ignored voltage drop across feedback network

Sinewave: 320mV_p , 12.8mA_p
Noise: 675mV_p , 27mA_p

Output stage drive options

No output feedback:

Output impedance of the CS stage has to be 50 Ohm
Output stage drives 50 Ohm

Sinewave: 320mV_p , 6.4mA_p
Noise: 675mV_p , 13.5mA_p

Only output voltage feedback:

Output impedance of the amplifier approximates zero
Insert 50 Ohm in series with the output to obtain 50 Ohm
Output stage drives 100 Ohm with two times the voltage
Ignored current drawn by feedback network

Sinewave: 640mV_p , 6.4mA_p
Noise: 1.3V_p , 13.5mA_p

Output current feedback:

Output impedance of the amplifier approximates infinity
Insert 50 Ohm in parallel with the output to obtain 50 Ohm
Output stage drives 25 Ohm with two times the current
Ignored voltage drop across feedback network

Sinewave: 320mV_p , 12.8mA_p
Noise: 675mV_p , 27mA_p

Output voltage and current feedback:

Output stage drive options

No output feedback:

Output impedance of the CS stage has to be 50 Ohm
Output stage drives 50 Ohm

Sinewave: 320mV_p , 6.4mA_p
Noise: 675mV_p , 13.5mA_p

Only output voltage feedback:

Output impedance of the amplifier approximates zero
Insert 50 Ohm in series with the output to obtain 50 Ohm
Output stage drives 100 Ohm with two times the voltage
Ignored current drawn by feedback network

Sinewave: 640mV_p , 6.4mA_p
Noise: 1.3V_p , 13.5mA_p

Output current feedback:

Output impedance of the amplifier approximates infinity
Insert 50 Ohm in parallel with the output to obtain 50 Ohm
Output stage drives 25 Ohm with two times the current
Ignored voltage drop across feedback network

Sinewave: 320mV_p , 12.8mA_p
Noise: 675mV_p , 27mA_p

Output voltage and current feedback:

Output impedance of the amplifier approximates 50 Ohm

Output stage drive options

No output feedback:

Output impedance of the CS stage has to be 50 Ohm
Output stage drives 50 Ohm

Sinewave: 320mV_p, 6.4mA_p
Noise: 675mV_p, 13.5mA_p

Only output voltage feedback:

Output impedance of the amplifier approximates zero
Insert 50 Ohm in series with the output to obtain 50 Ohm
Output stage drives 100 Ohm with two times the voltage
Ignored current drawn by feedback network

Sinewave: 640mV_p, 6.4mA_p
Noise: 1.3V_p, 13.5mA_p

Output current feedback:

Output impedance of the amplifier approximates infinity
Insert 50 Ohm in parallel with the output to obtain 50 Ohm
Output stage drives 25 Ohm with two times the current
Ignored voltage drop across feedback network

Sinewave: 320mV_p, 12.8mA_p
Noise: 675mV_p, 27mA_p

Output voltage and current feedback:

Output impedance of the amplifier approximates 50 Ohm
Output stage drives 50 Ohm with required voltage/current

Output stage drive options

No output feedback:

Output impedance of the CS stage has to be 50 Ohm
Output stage drives 50 Ohm

Sinewave: 320mV_p , 6.4mA_p
Noise: 675mV_p , 13.5mA_p

Only output voltage feedback:

Output impedance of the amplifier approximates zero
Insert 50 Ohm in series with the output to obtain 50 Ohm
Output stage drives 100 Ohm with two times the voltage
Ignored current drawn by feedback network

Sinewave: 640mV_p , 6.4mA_p
Noise: 1.3V_p , 13.5mA_p

Output current feedback:

Output impedance of the amplifier approximates infinity
Insert 50 Ohm in parallel with the output to obtain 50 Ohm
Output stage drives 25 Ohm with two times the current
Ignored voltage drop across feedback network

Sinewave: 320mV_p , 12.8mA_p
Noise: 675mV_p , 27mA_p

Output voltage and current feedback:

Output impedance of the amplifier approximates 50 Ohm
Output stage drives 50 Ohm with required voltage/current

Sinewave: 320mV_p , 6.4mA_p

Output stage drive options

No output feedback:

Output impedance of the CS stage has to be 50 Ohm
Output stage drives 50 Ohm

Sinewave: 320mV_p, 6.4mA_p
Noise: 675mV_p, 13.5mA_p

Only output voltage feedback:

Output impedance of the amplifier approximates zero
Insert 50 Ohm in series with the output to obtain 50 Ohm
Output stage drives 100 Ohm with two times the voltage
Ignored current drawn by feedback network

Sinewave: 640mV_p, 6.4mA_p
Noise: 1.3V_p, 13.5mA_p

Output current feedback:

Output impedance of the amplifier approximates infinity
Insert 50 Ohm in parallel with the output to obtain 50 Ohm
Output stage drives 25 Ohm with two times the current
Ignored voltage drop across feedback network

Sinewave: 320mV_p, 12.8mA_p
Noise: 675mV_p, 27mA_p

Output voltage and current feedback:

Output impedance of the amplifier approximates 50 Ohm
Output stage drives 50 Ohm with required voltage/current

Sinewave: 320mV_p, 6.4mA_p
Noise: 675mV_p, 13.5mA_p

Output stage drive options

No output feedback:

Output impedance of the CS stage has to be 50 Ohm
Output stage drives 50 Ohm

Sinewave: 320mV_p , 6.4mA_p
Noise: 675mV_p , 13.5mA_p

Only output voltage feedback:

Output impedance of the amplifier approximates zero
Insert 50 Ohm in series with the output to obtain 50 Ohm
Output stage drives 100 Ohm with two times the voltage
Ignored current drawn by feedback network

Sinewave: 640mV_p , 6.4mA_p
Noise: 1.3V_p , 13.5mA_p

Output current feedback:

Output impedance of the amplifier approximates infinity
Insert 50 Ohm in parallel with the output to obtain 50 Ohm
Output stage drives 25 Ohm with two times the current
Ignored voltage drop across feedback network

Sinewave: 320mV_p , 12.8mA_p
Noise: 675mV_p , 27mA_p

Output voltage and current feedback:

Output impedance of the amplifier approximates 50 Ohm
Output stage drives 50 Ohm with required voltage/current
Ignored voltage drop across series feedback network
and current drawn by parallel feedback network

Sinewave: 320mV_p , 6.4mA_p
Noise: 675mV_p , 13.5mA_p

Output stage drive options

No output feedback:

Output impedance of the CS stage has to be 50 Ohm
Output stage drives 50 Ohm

Sinewave: 320mV_p , 6.4mA_p
Noise: 675mV_p , 13.5mA_p

Only output voltage feedback:

Output impedance of the amplifier approximates zero
Insert 50 Ohm in series with the output to obtain 50 Ohm
Output stage drives 100 Ohm with two times the voltage
Ignored current drawn by feedback network

Sinewave: 640mV_p , 6.4mA_p
Noise: 1.3V_p , 13.5mA_p

Output current feedback:

Output impedance of the amplifier approximates infinity
Insert 50 Ohm in parallel with the output to obtain 50 Ohm
Output stage drives 25 Ohm with two times the current
Ignored voltage drop across feedback network

Sinewave: 320mV_p , 12.8mA_p
Noise: 675mV_p , 27mA_p

Output voltage and current feedback:

Output impedance of the amplifier approximates 50 Ohm
Output stage drives 50 Ohm with required voltage/current
Ignored voltage drop across series feedback network
and current drawn by parallel feedback network

Sinewave: 320mV_p , 6.4mA_p
Noise: 675mV_p , 13.5mA_p

Structured Electronic Design

EE4109

Homework 1

Design of a CS stage,
Driving the output stage

Anton J.M. Montagne

Output stage drive conditions

Output stage drive conditions

The CS output stage will be driven from:

Output stage drive conditions

The CS output stage will be driven from:

Preceding stage:

Output stage drive conditions

The CS output stage will be driven from:

Preceding stage:

Peak-peak drive voltage maximally equals the power supply voltage

Output stage drive conditions

The CS output stage will be driven from:

Preceding stage:

Peak-peak drive voltage maximally equals the power supply voltage

$$1.8V_{pp}$$

Output stage drive conditions

The CS output stage will be driven from:

Preceding stage:

Peak-peak drive voltage maximally equals the power supply voltage

$$1.8V_{pp}$$

Antenna:

Output stage drive conditions

The CS output stage will be driven from:

Preceding stage:

Peak-peak drive voltage maximally equals the power supply voltage

$$1.8V_{pp}$$

Antenna:

Peak-peak drive voltage maximally equals the peak-peak antenna voltage

Output stage drive conditions

The CS output stage will be driven from:

Preceding stage:

Peak-peak drive voltage maximally equals the power supply voltage

$$1.8V_{pp}$$

Antenna:

Peak-peak drive voltage maximally equals the peak-peak antenna voltage

$$0.45 \times 0.18 = 81mV_{rms}$$

Output stage drive conditions

The CS output stage will be driven from:

Preceding stage:

Peak-peak drive voltage maximally equals the power supply voltage

$$1.8V_{pp}$$

Antenna:

Peak-peak drive voltage maximally equals the peak-peak antenna voltage

$$0.45 \times 0.18 = 81mV_{rms}$$

$$\text{Sinewave: } 230mV_{pp}$$

Output stage drive conditions

The CS output stage will be driven from:

Preceding stage:

Peak-peak drive voltage maximally equals the power supply voltage

$$1.8V_{pp}$$

Antenna:

Peak-peak drive voltage maximally equals the peak-peak antenna voltage

$$0.45 \times 0.18 = 81mV_{rms}$$

Sinewave: $230mV_{pp}$

Noise: $490mV_{pp}$

Output stage drive conditions

The CS output stage will be driven from:

Preceding stage:

Peak-peak drive voltage maximally equals the power supply voltage

$$1.8V_{pp}$$

Antenna:

Peak-peak drive voltage maximally equals the peak-peak antenna voltage

$$0.45 \times 0.18 = 81mV_{rms}$$

$$\text{Sinewave: } 230mV_{pp}$$

$$\text{Noise: } 490mV_{pp}$$

Structured Electronic Design

EE4109

Homework 1

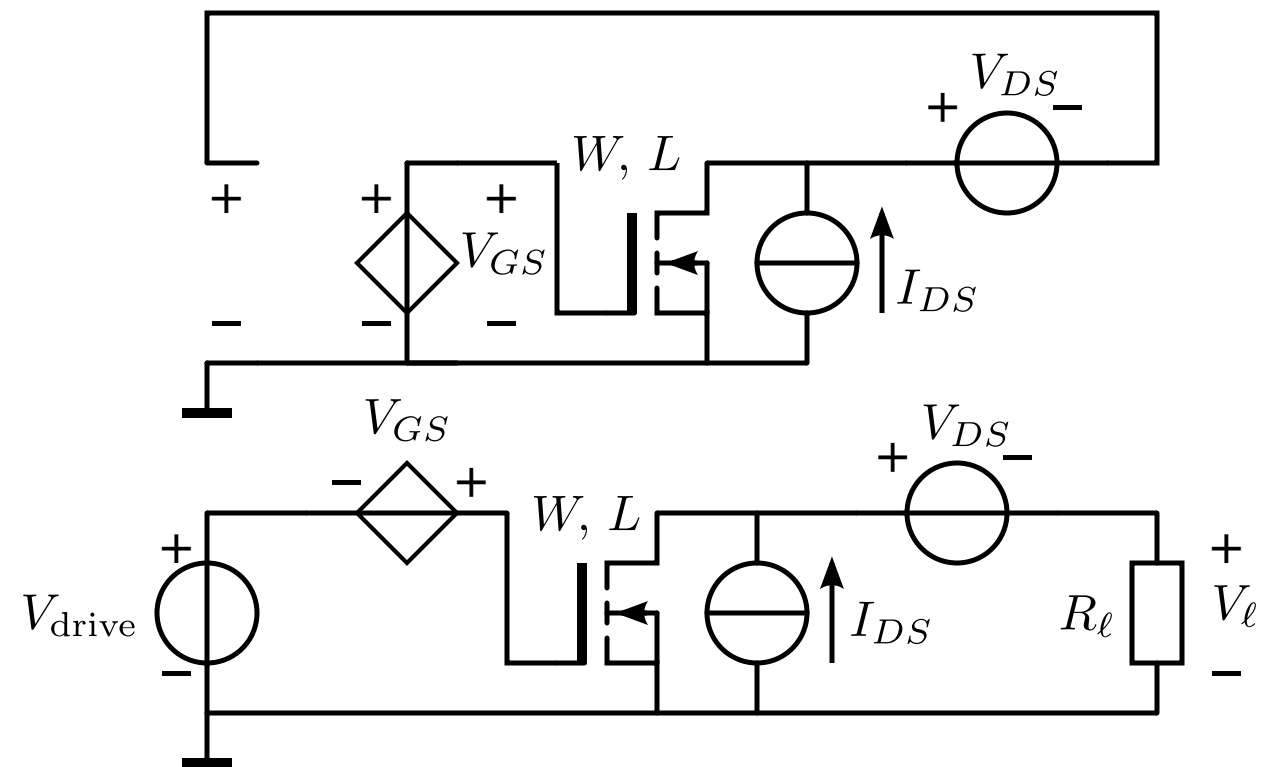
Design of a CS stage,
Test benches output stage

Anton J.M. Montagne

Test benches output stage LTspice

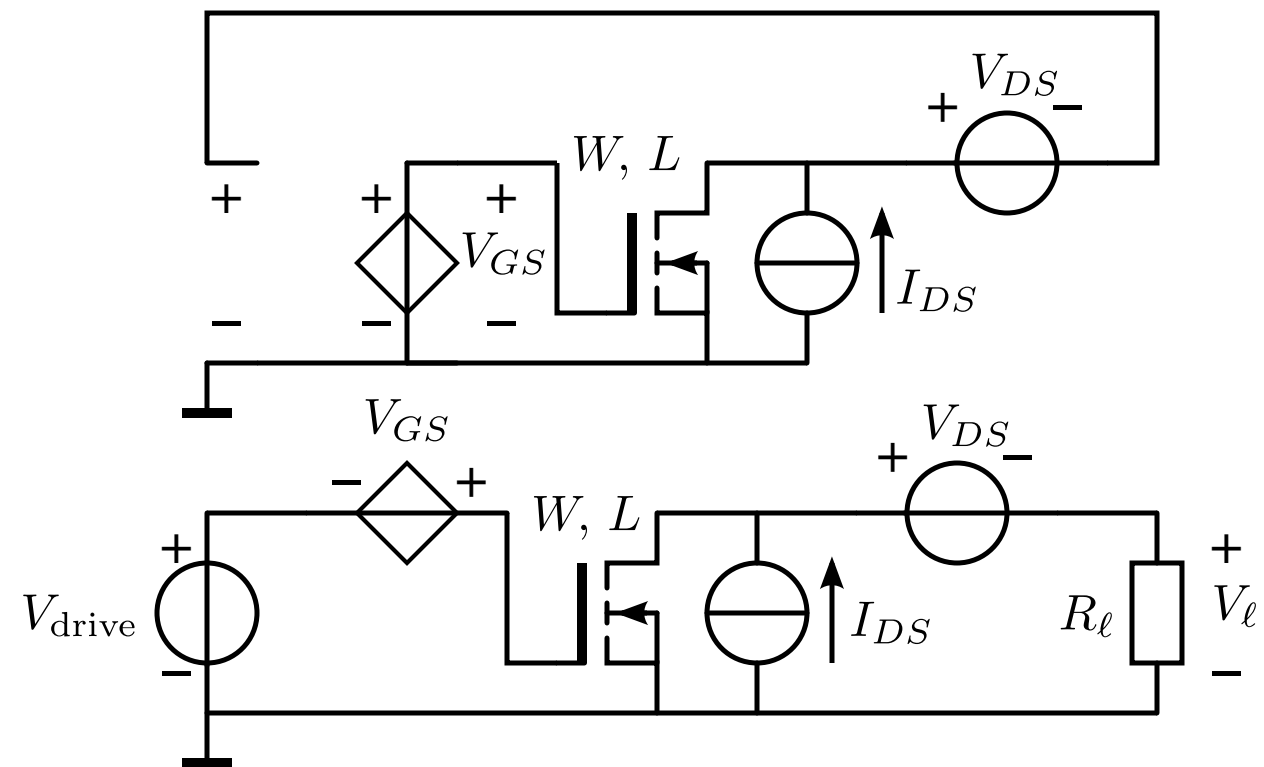
Test benches output stage LTspice

Indirect feedback biasing

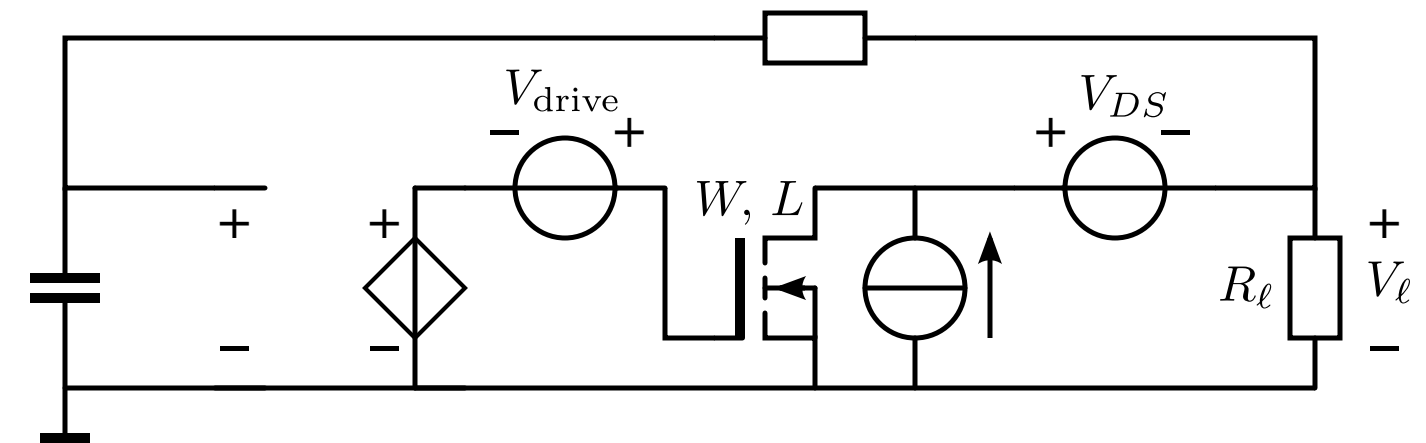


Test benches output stage LTspice

Indirect feedback biasing

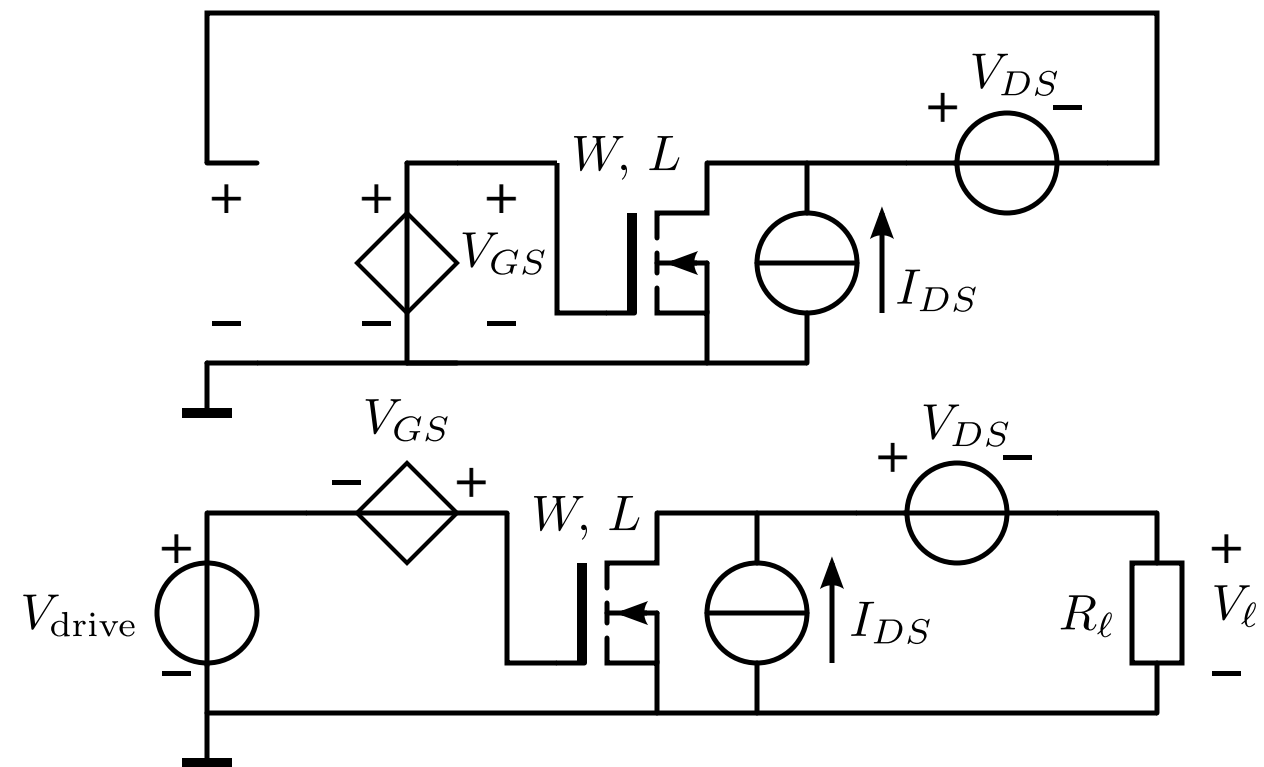


Direct feedback biasing

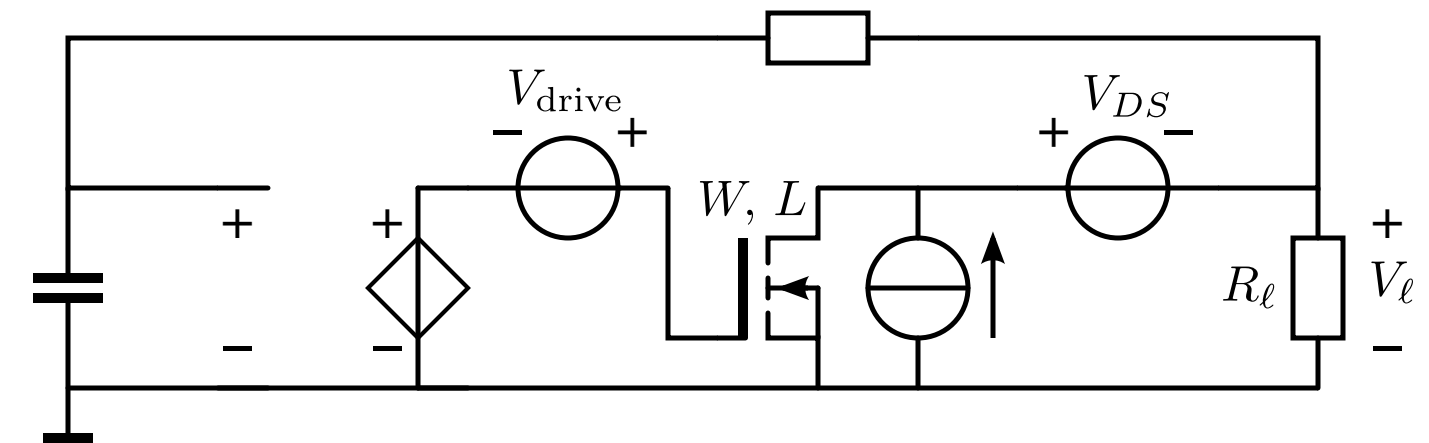


Test benches output stage LTspice

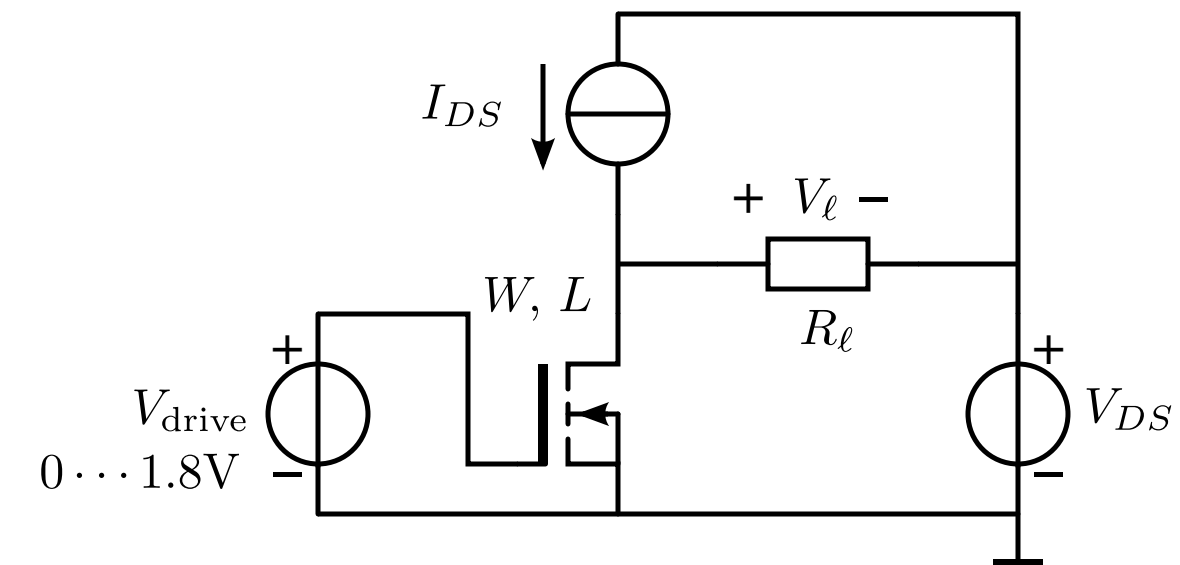
Indirect feedback biasing



Direct feedback biasing

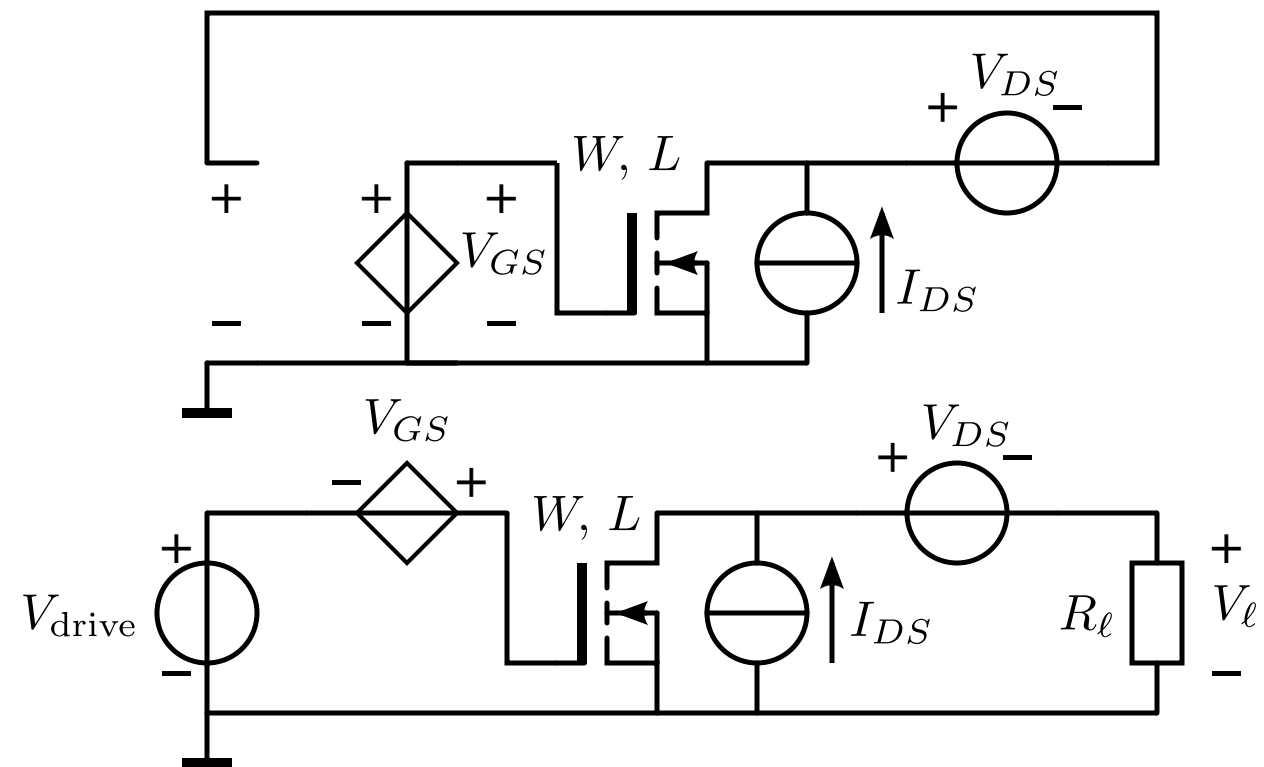


Swept input



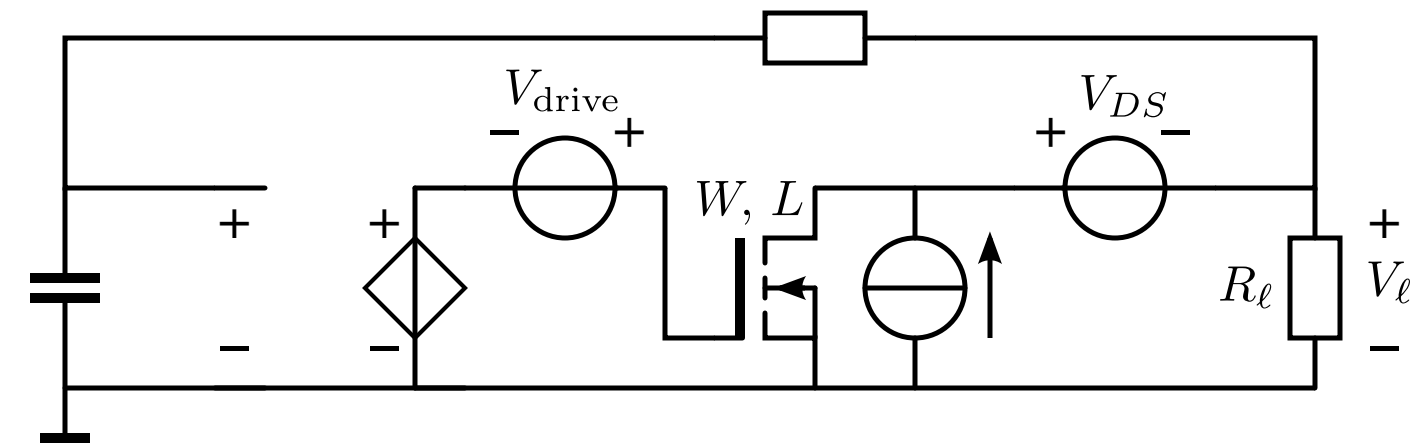
Test benches output stage LTspice

Indirect feedback biasing

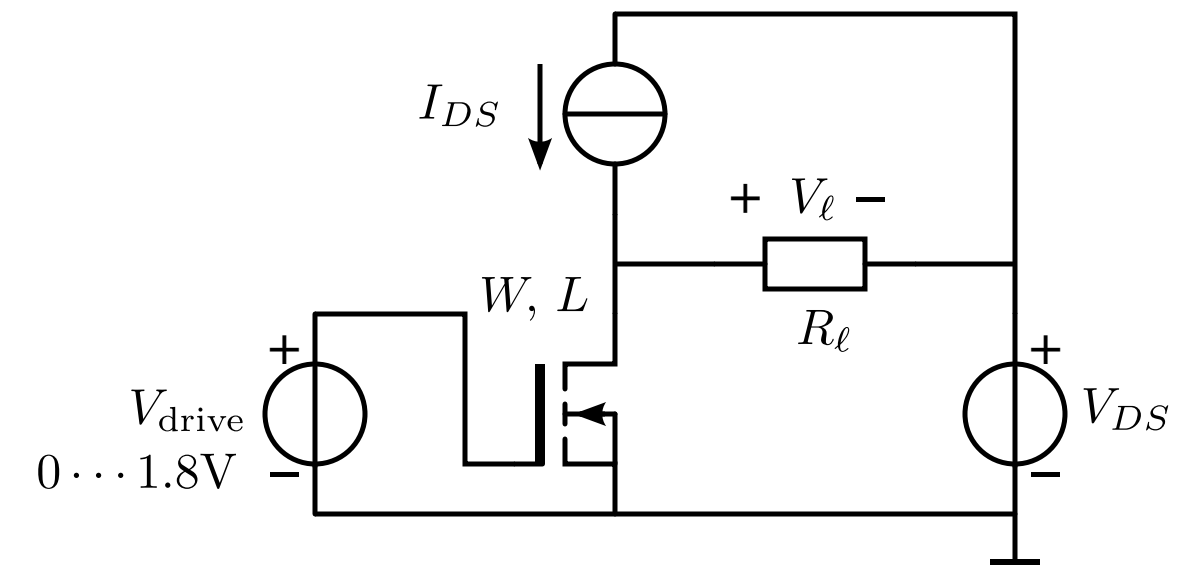


V_{DS} Larger than the peak voltage drive requirement

Direct feedback biasing

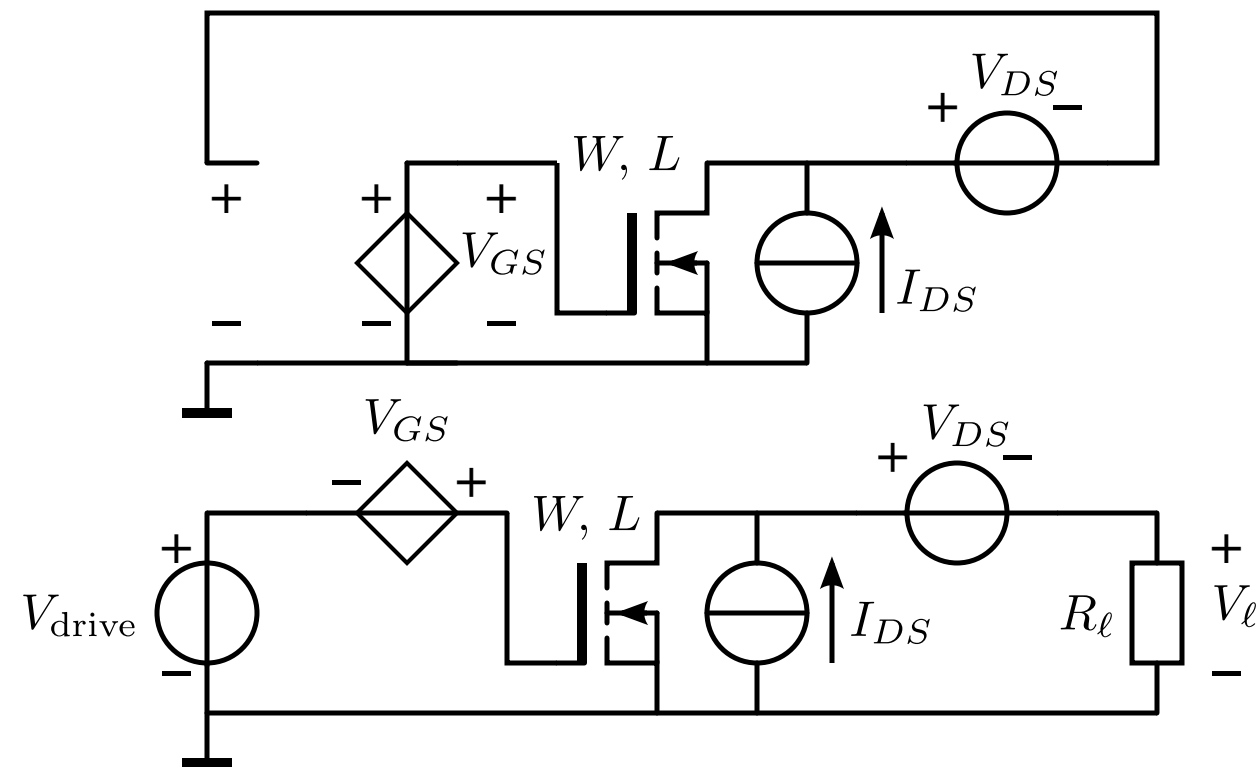


Swept input



Test benches output stage LTspice

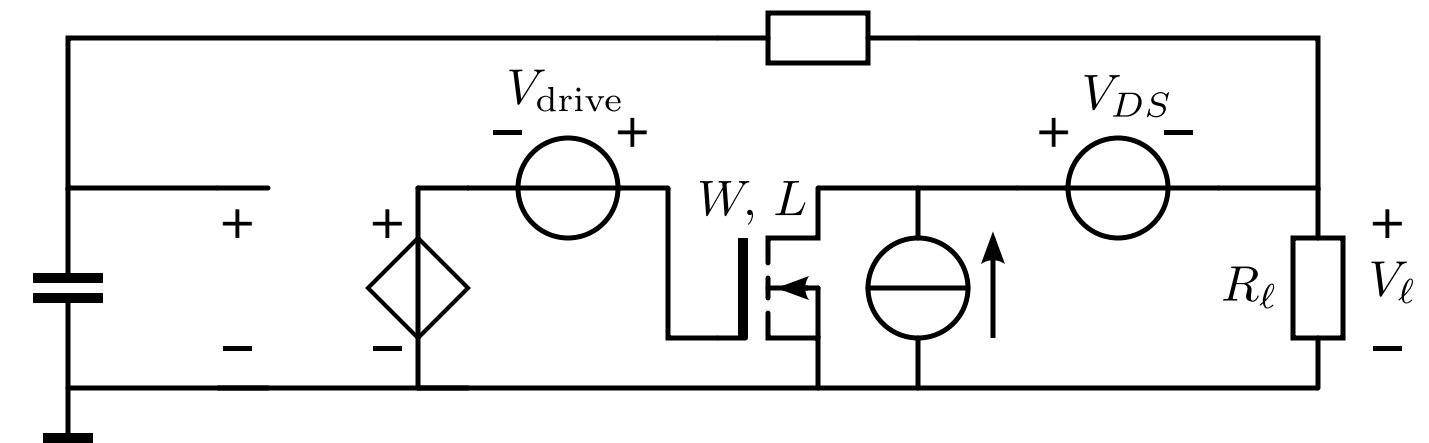
Indirect feedback biasing



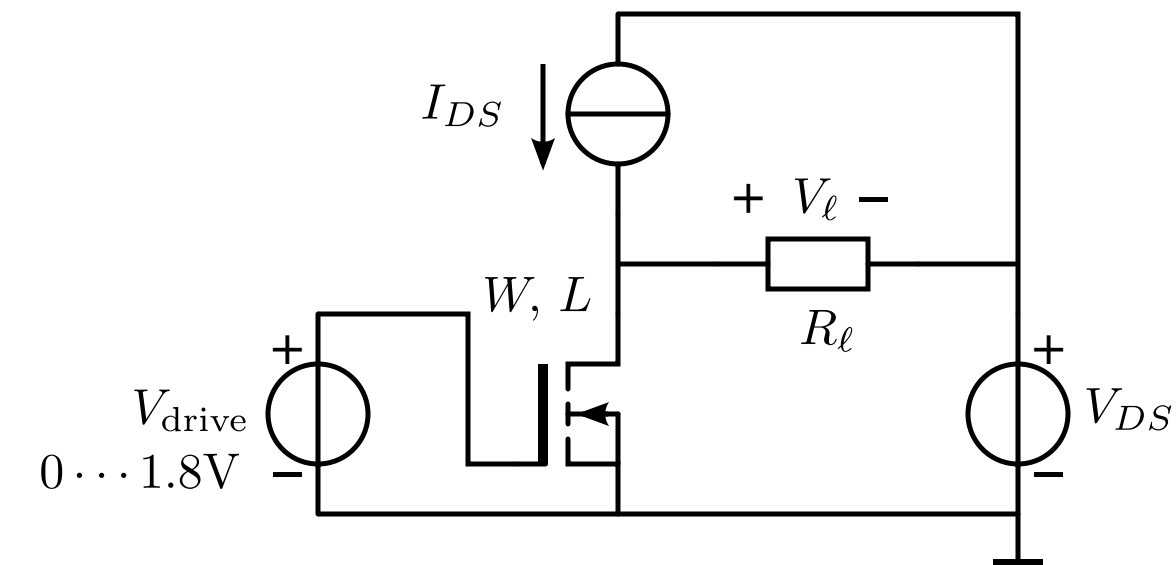
V_{DS} Larger than the peak voltage drive requirement

I_{DS} Larger than the peak current drive requirement

Direct feedback biasing

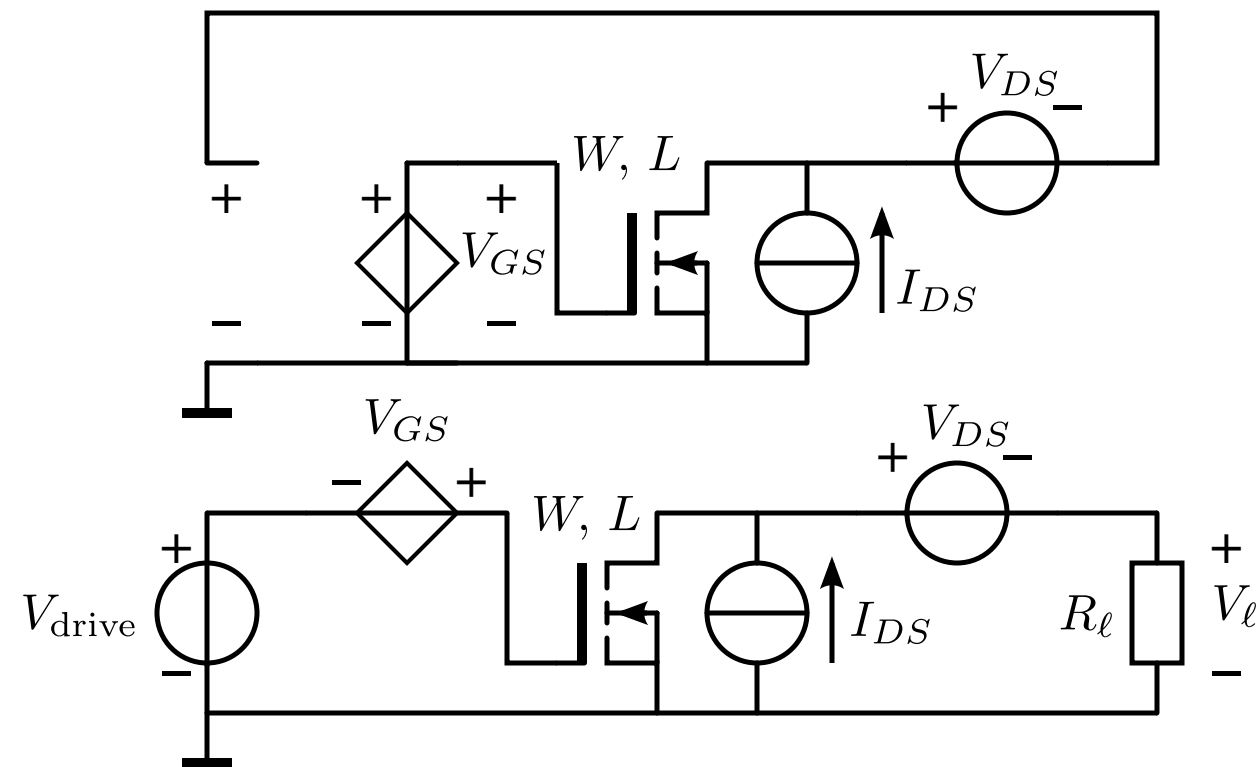


Swept input



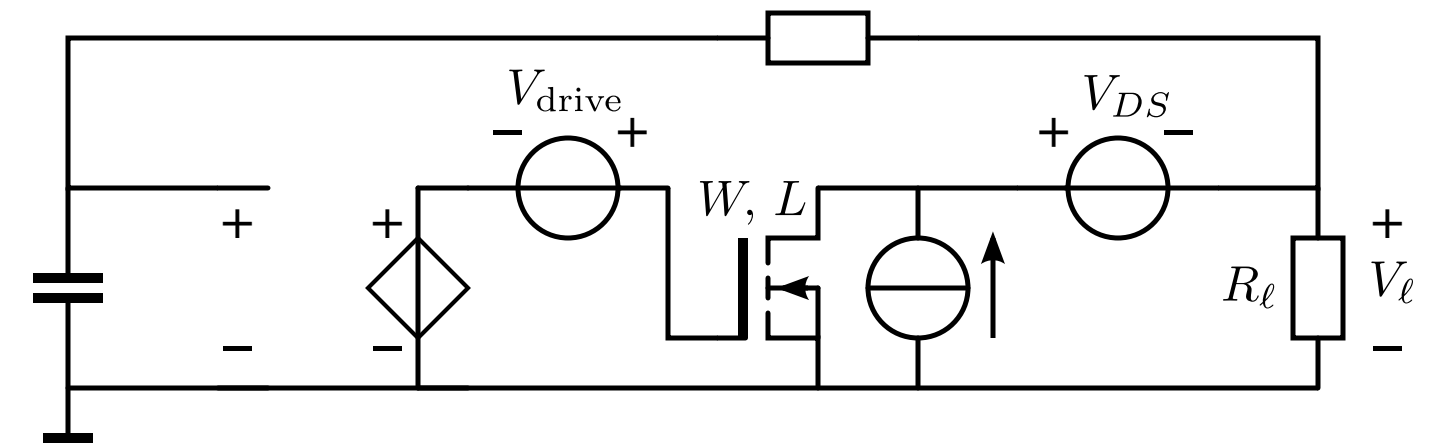
Test benches output stage LTspice

Indirect feedback biasing

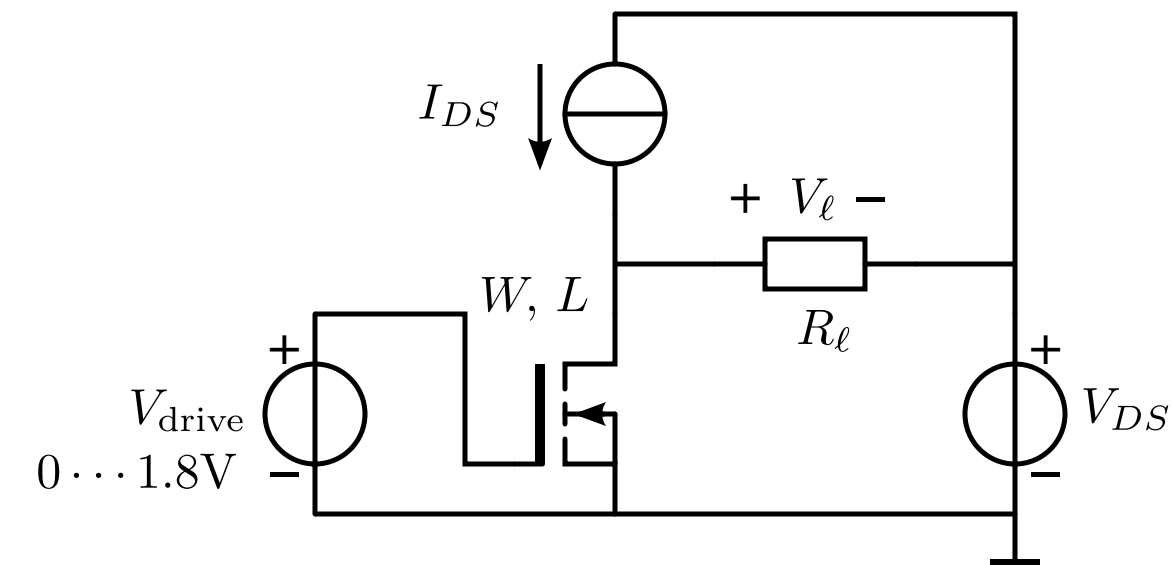


- V_{DS} Larger than the peak voltage drive requirement
- I_{DS} Larger than the peak current drive requirement
- L Smallest value (lowest voltage drive requirement)

Direct feedback biasing

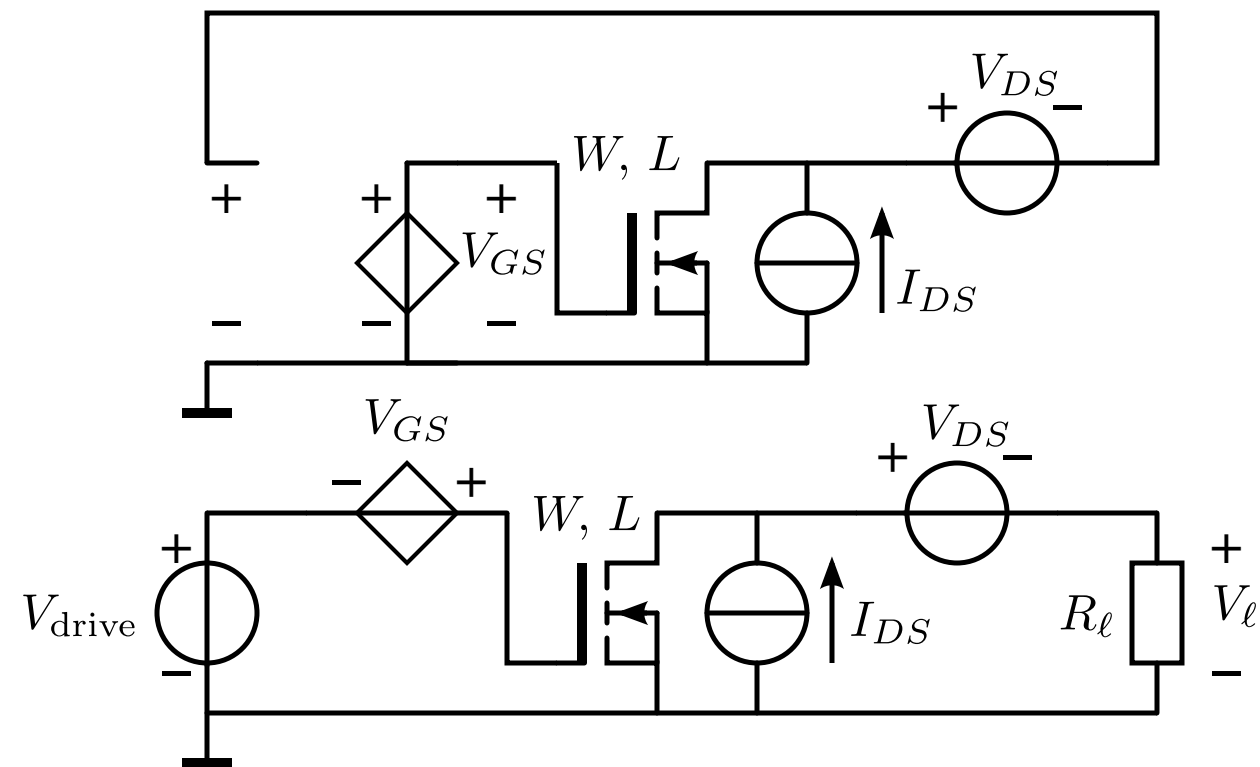


Swept input



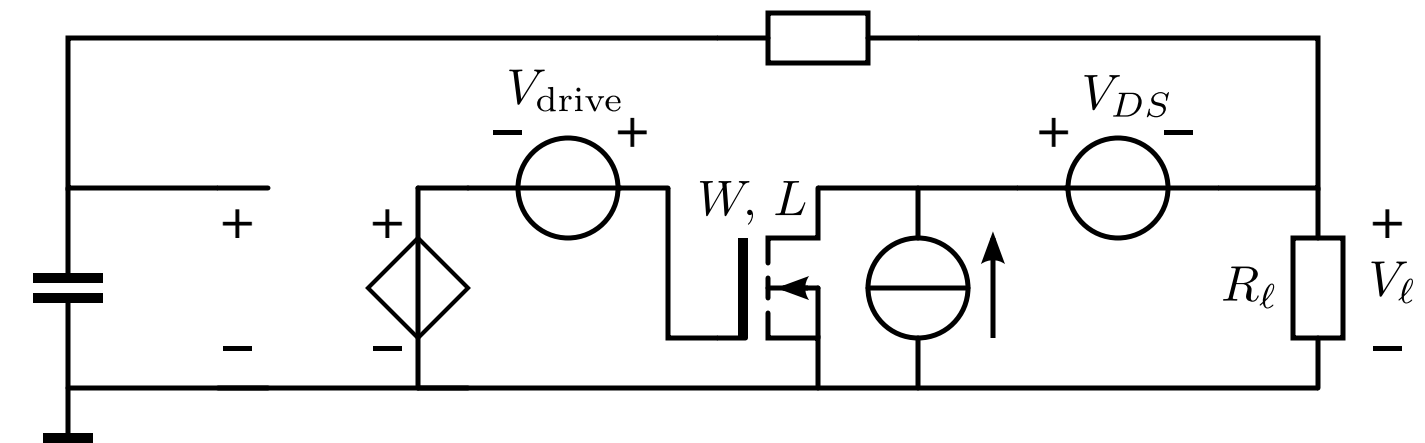
Test benches output stage LTspice

Indirect feedback biasing

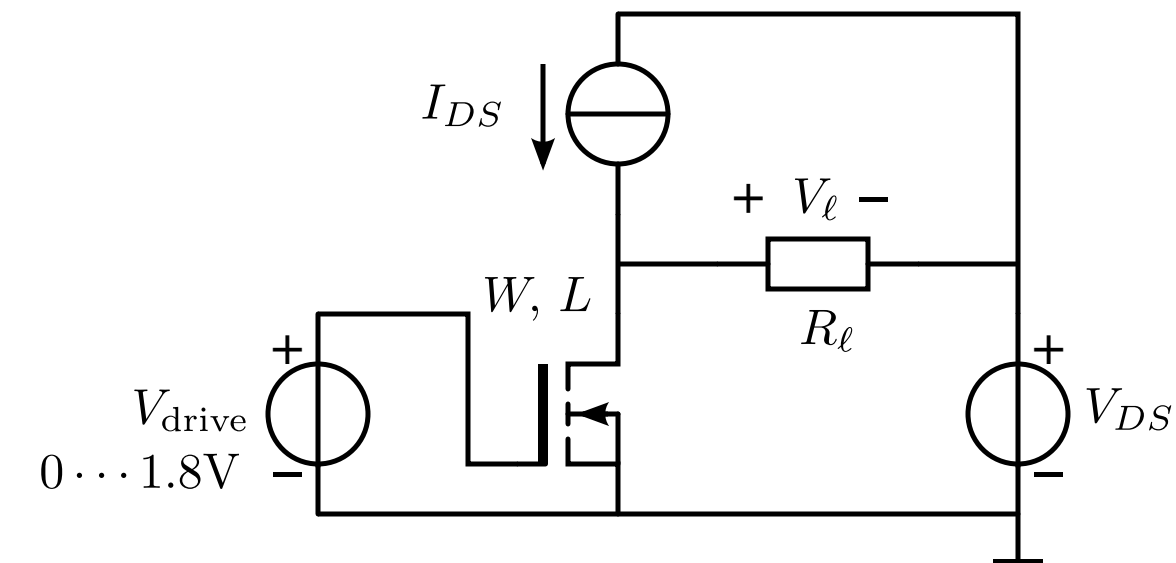


- V_{DS} Larger than the peak voltage drive requirement
- I_{DS} Larger than the peak current drive requirement
- L Smallest value (lowest voltage drive requirement)
- W Large enough to ensure sufficiently large drive capability

Direct feedback biasing

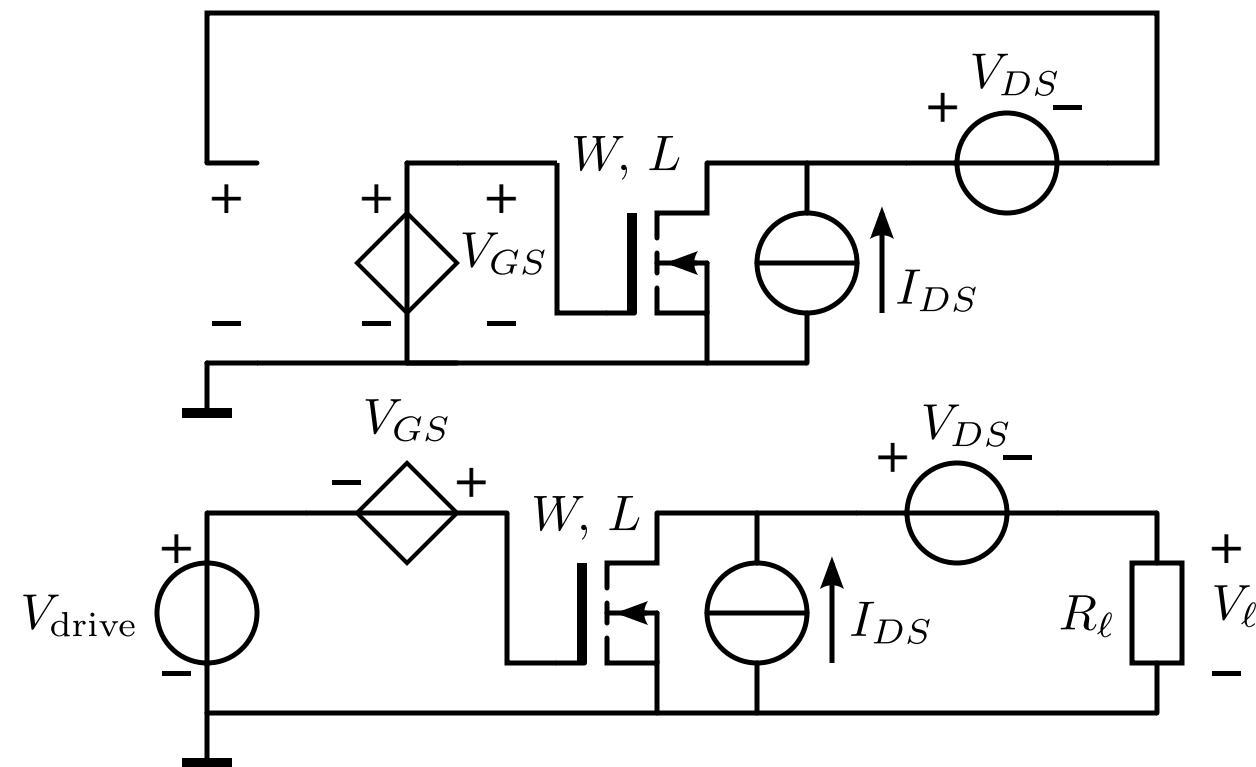


Swept input



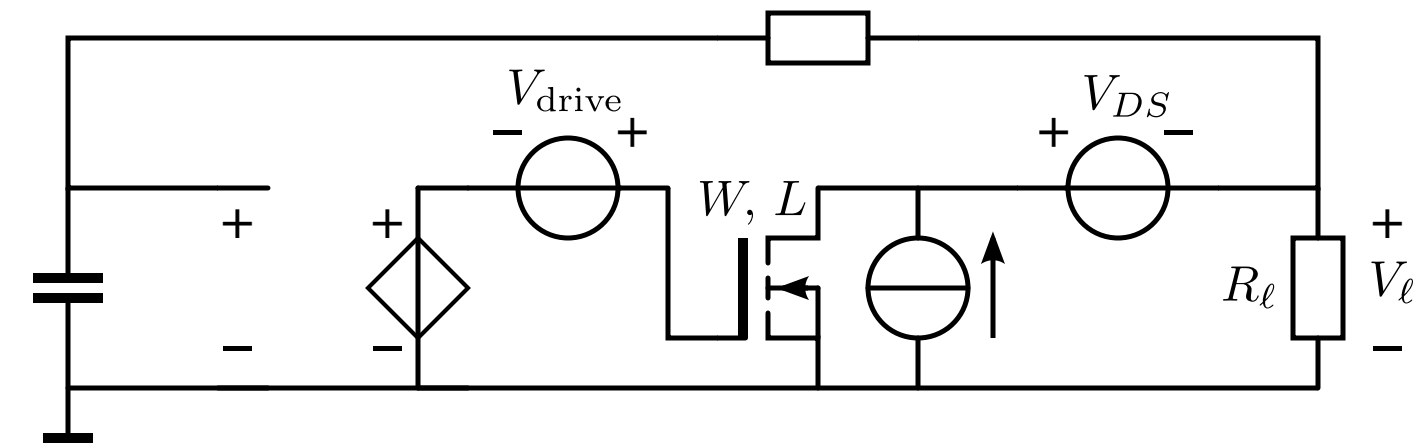
Test benches output stage LTspice

Indirect feedback biasing

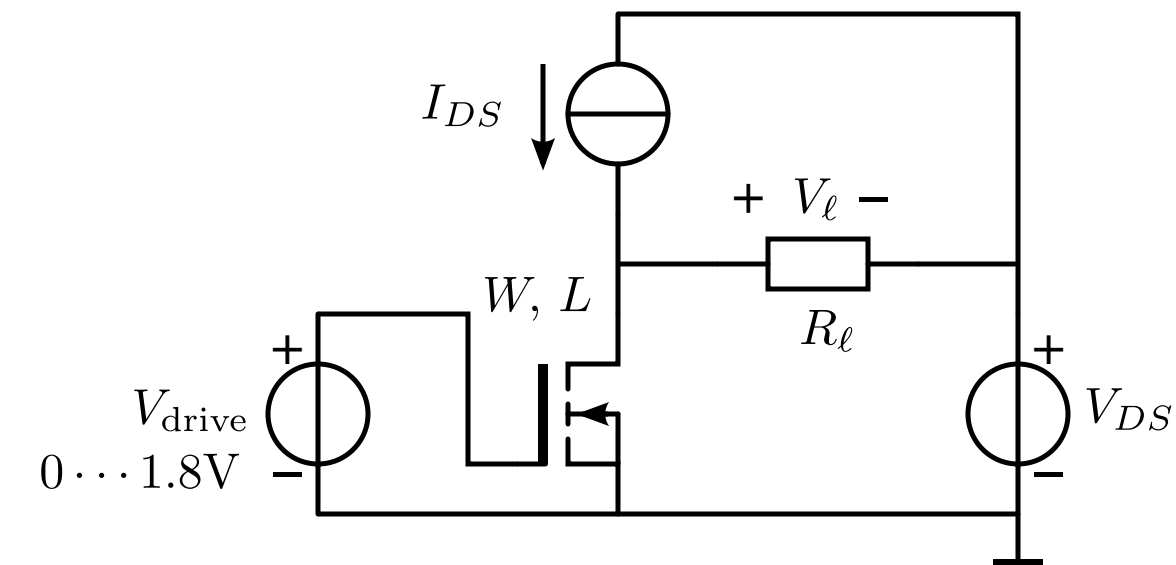


- V_{DS} Larger than the peak voltage drive requirement
- I_{DS} Larger than the peak current drive requirement
- L Smallest value (lowest voltage drive requirement)
- W Large enough to ensure sufficiently large drive capability

Direct feedback biasing



Swept input



Structured Electronic Design

EE4109

Homework 1

Design of a CS stage,
Input stage design

Anton J.M. Montagne

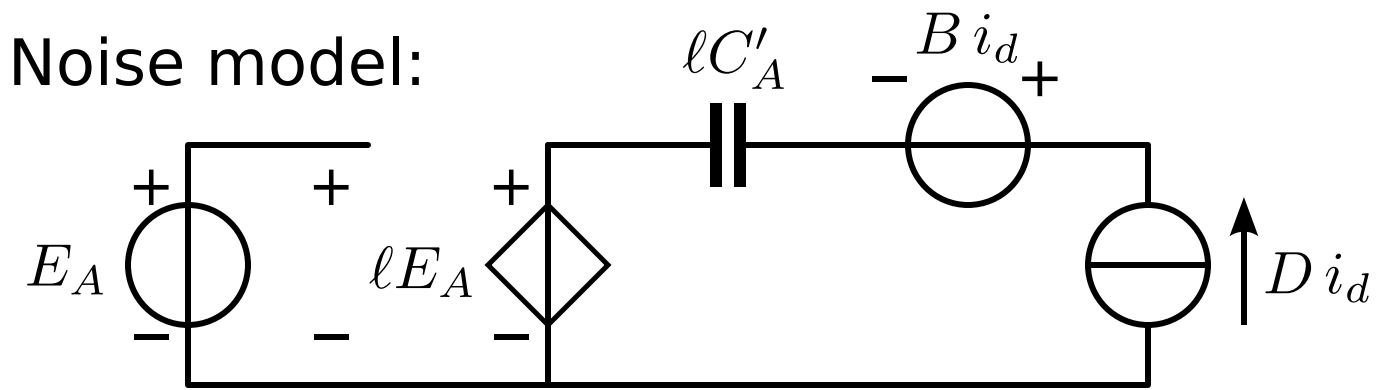
Design input stage noise performance: SLiCAP

Design input stage noise performance: SLiCAP

Noise model:

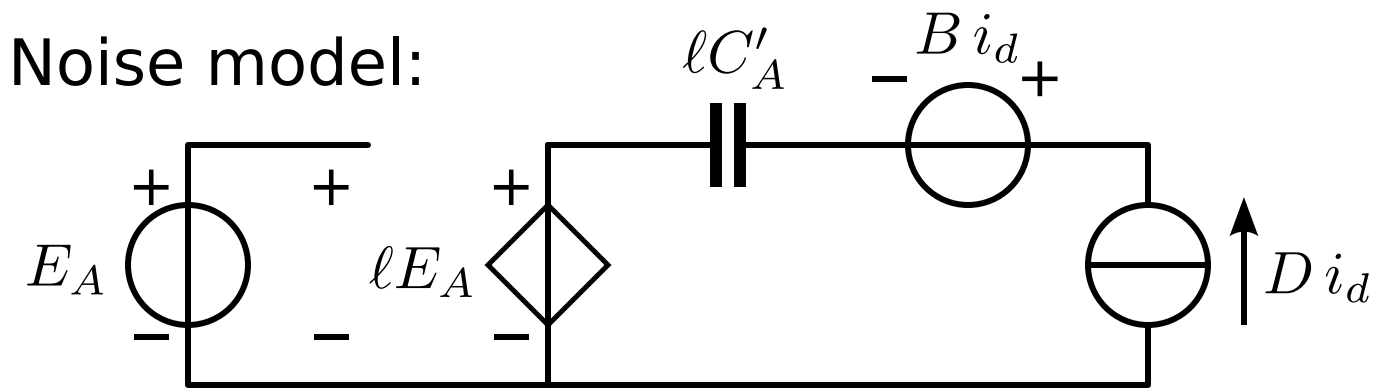
Design input stage noise performance: SLiCAP

Noise model:



Design input stage noise performance: SLiCAP

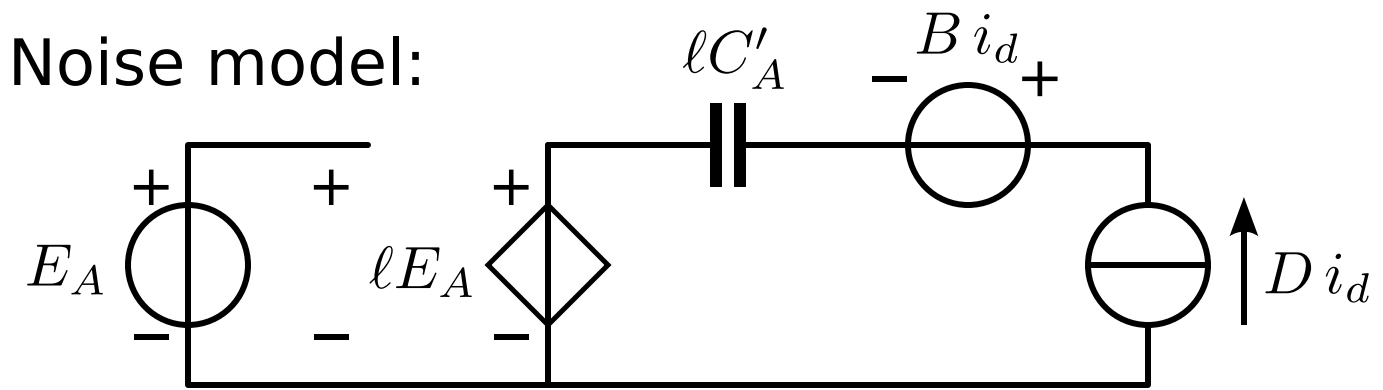
Noise model:



Given:

Design input stage noise performance: SLiCAP

Noise model:

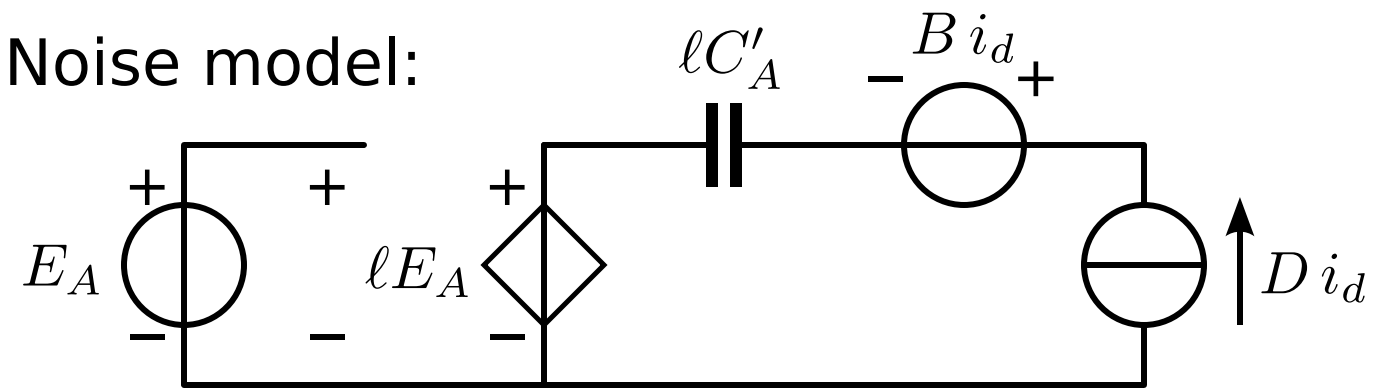


Given:

$$\begin{cases} C'_A = 8.33 \times 10^{-12} \text{ [Fm}^{-1}\text{]} \\ \ell = 0.18 \text{ [m]} \end{cases}$$

Design input stage noise performance: SLiCAP

Noise model:

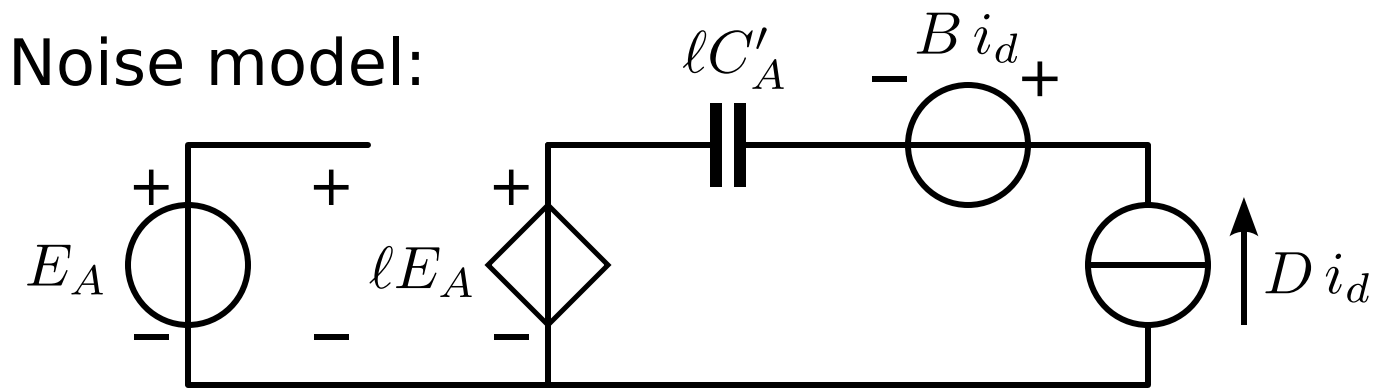


Given: $\begin{cases} C'_A = 8.33 \times 10^{-12} \text{ [Fm}^{-1}\text{]} \\ \ell = 0.18 \text{ [m]} \end{cases}$

Required:

Design input stage noise performance: SLiCAP

Noise model:



Given:

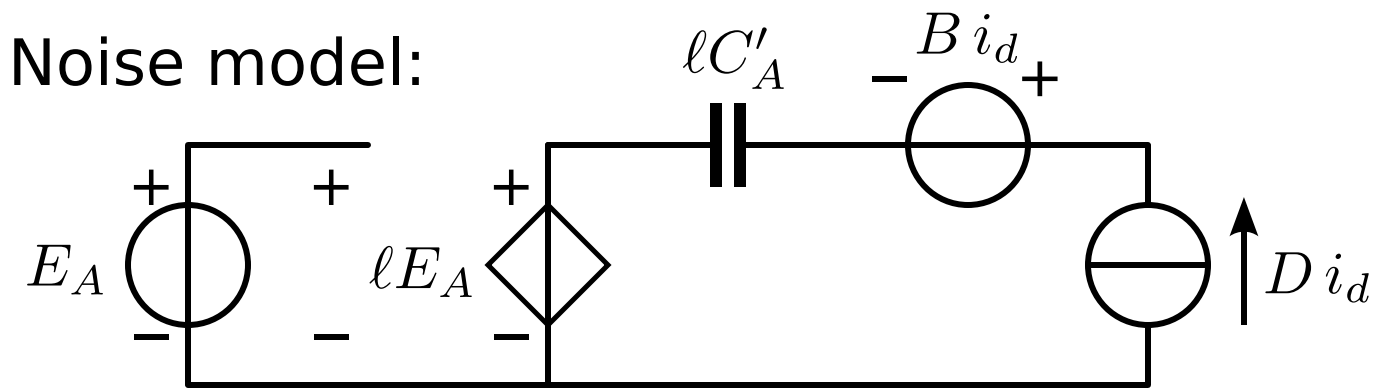
$$\begin{cases} C'_A = 8.33 \times 10^{-12} \text{ [Fm}^{-1}\text{]} \\ \ell = 0.18 \text{ [m]} \end{cases}$$

Required:

$$\begin{cases} S_E = 25 \times 10^{-18} \text{ [V}^2\text{m}^{-2}\text{Hz}^{-1}\text{]} \\ f_\ell = 100 \times 10^3 \text{ [Hz]} \end{cases}$$

Design input stage noise performance: SLiCAP

Noise model:



Given:

$$\begin{cases} C'_A = 8.33 \times 10^{-12} \text{ [Fm}^{-1}\text{]} \\ \ell = 0.18 \text{ [m]} \end{cases}$$

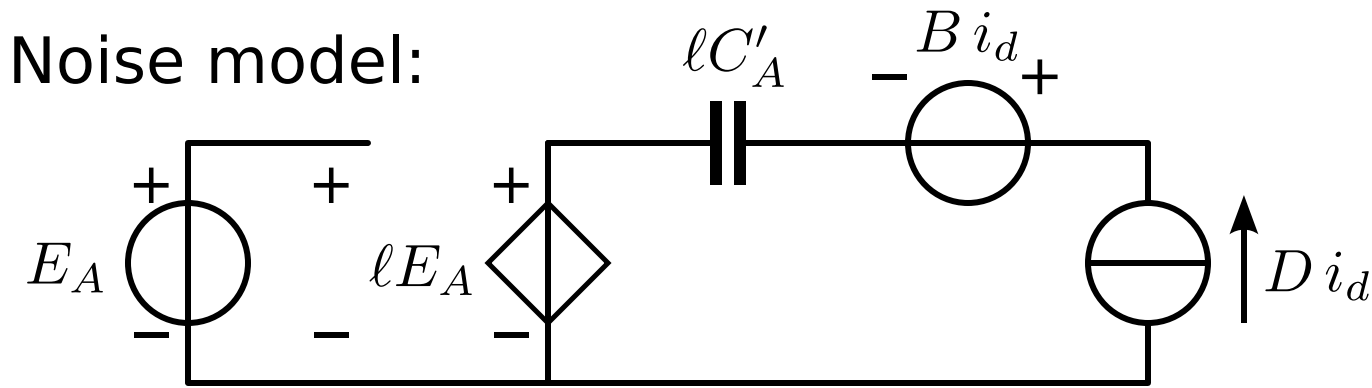
Required:

$$\begin{cases} S_E = 25 \times 10^{-18} \text{ [V}^2\text{m}^{-2}\text{Hz}^{-1}\text{]} \\ f_\ell = 100 \times 10^3 \text{ [Hz]} \end{cases}$$

Determine I_{DS} , L , W based on spectrum noise floor and corner frequency 1/f noise

Design input stage noise performance: SLiCAP

Noise model:



Given:

$$\begin{cases} C'_A = 8.33 \times 10^{-12} \text{ [Fm}^{-1}\text{]} \\ \ell = 0.18 \text{ [m]} \end{cases}$$

Required:

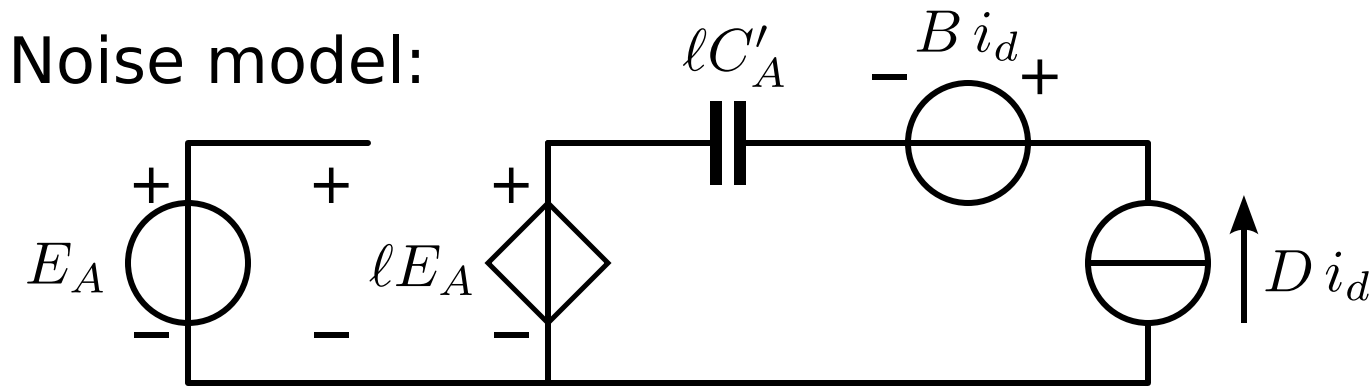
$$\begin{cases} S_E = 25 \times 10^{-18} \text{ [V}^2\text{m}^{-2}\text{Hz}^{-1}\text{]} \\ f_\ell = 100 \times 10^3 \text{ [Hz]} \end{cases}$$

Determine I_{DS} , L , W based on spectrum noise floor and corner frequency 1/f noise

$$S_E = \frac{1}{\ell^2} \left(\frac{4kT\Gamma n}{g_m} \left(1 + \frac{c_{iss}}{\ell C'_A} \right)^2 + \frac{2KF}{3c_{iss}} \left(1 + \frac{c_{iss}}{\ell C'_A} \right)^2 \frac{1}{f} \right)$$

Design input stage noise performance: SLiCAP

Noise model:



Given:

$$\begin{cases} C'_A = 8.33 \times 10^{-12} \text{ [Fm}^{-1}\text{]} \\ \ell = 0.18 \text{ [m]} \end{cases}$$

Required:

$$\begin{cases} S_E = 25 \times 10^{-18} \text{ [V}^2\text{m}^{-2}\text{Hz}^{-1}\text{]} \\ f_\ell = 100 \times 10^3 \text{ [Hz]} \end{cases}$$

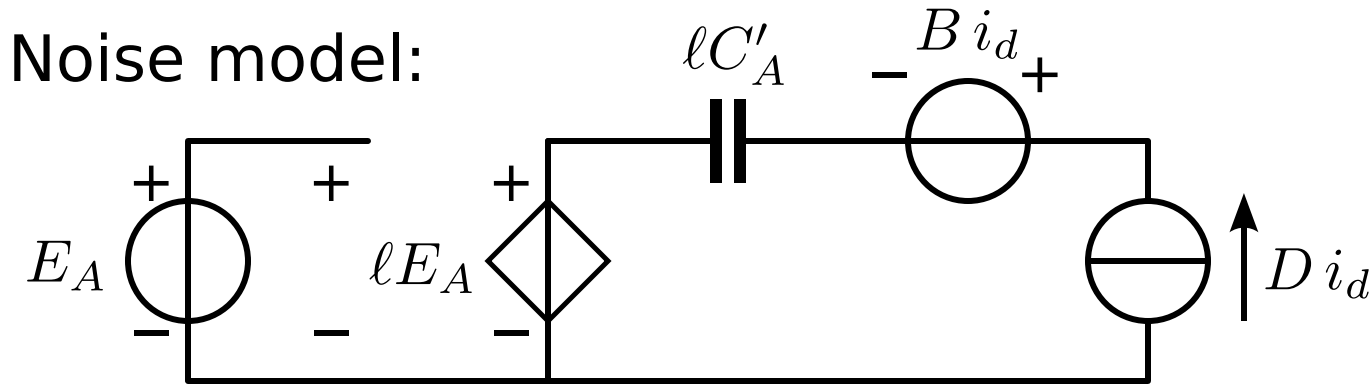
Determine I_{DS} , L , W based on spectrum noise floor and corner frequency 1/f noise

$$S_E = \frac{1}{\ell^2} \left(\frac{4kT\Gamma n}{g_m} \left(1 + \frac{c_{iss}}{\ell C'_A} \right)^2 + \frac{2KF}{3c_{iss}} \left(1 + \frac{c_{iss}}{\ell C'_A} \right)^2 \frac{1}{f} \right)$$

Lowest corner frequency 1/f noise if $c_{iss} = \ell C'_A$

Design input stage noise performance: SLiCAP

Noise model:



Given:

$$\begin{cases} C'_A = 8.33 \times 10^{-12} \text{ [Fm}^{-1}\text{]} \\ \ell = 0.18 \text{ [m]} \end{cases}$$

Required:

$$\begin{cases} S_E = 25 \times 10^{-18} \text{ [V}^2\text{m}^{-2}\text{Hz}^{-1}\text{]} \\ f_\ell = 100 \times 10^3 \text{ [Hz]} \end{cases}$$

Determine I_{DS} , L , W based on spectrum noise floor and corner frequency 1/f noise

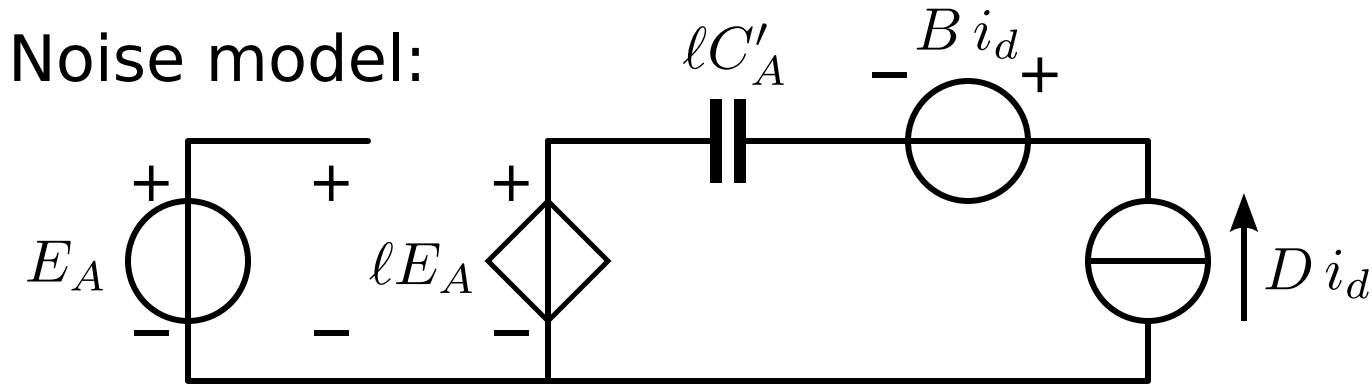
$$S_E = \frac{1}{\ell^2} \left(\frac{4kT\Gamma n}{g_m} \left(1 + \frac{c_{iss}}{\ell C'_A} \right)^2 + \frac{2KF}{3c_{iss}} \left(1 + \frac{c_{iss}}{\ell C'_A} \right)^2 \frac{1}{f} \right)$$

Lowest corner frequency 1/f noise if $c_{iss} = \ell C'_A$

Minimum length for given requirements and process: $\ell > 2 \sqrt[3]{\frac{KF}{3S_E C'_A f_\ell}}$

Design input stage noise performance: SLiCAP

Noise model:



Given:

$$\begin{cases} C'_A = 8.33 \times 10^{-12} \text{ [Fm}^{-1}\text{]} \\ \ell = 0.18 \text{ [m]} \end{cases}$$

Required:

$$\begin{cases} S_E = 25 \times 10^{-18} \text{ [V}^2\text{m}^{-2}\text{Hz}^{-1}\text{]} \\ f_\ell = 100 \times 10^3 \text{ [Hz]} \end{cases}$$

Determine I_{DS} , L , W based on spectrum noise floor and corner frequency 1/f noise

$$S_E = \frac{1}{\ell^2} \left(\frac{4kT\Gamma n}{g_m} \left(1 + \frac{c_{iss}}{\ell C'_A} \right)^2 + \frac{2KF}{3c_{iss}} \left(1 + \frac{c_{iss}}{\ell C'_A} \right)^2 \frac{1}{f} \right)$$

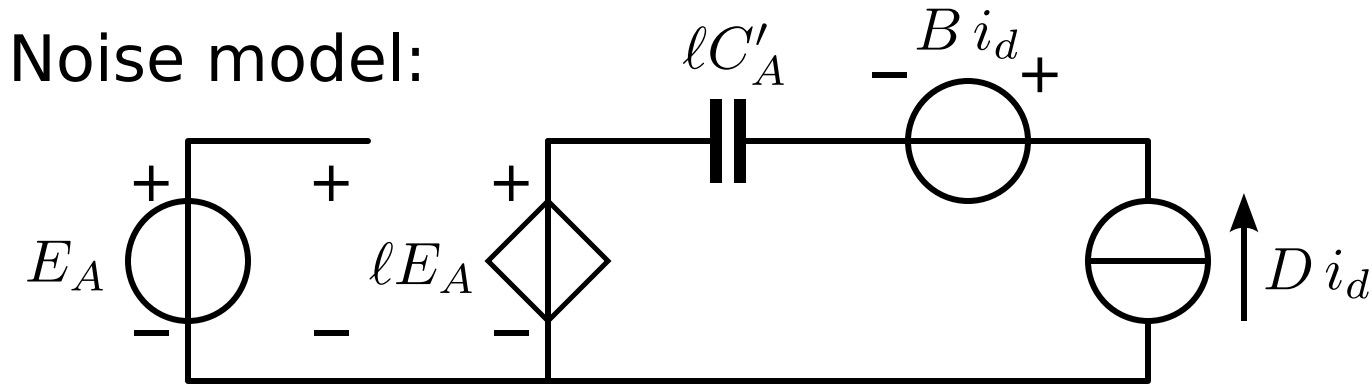
Lowest corner frequency 1/f noise if $c_{iss} = \ell C'_A$

Minimum length for given requirements and process: $\ell > 2 \sqrt[3]{\frac{KF}{3S_E C'_A f_\ell}}$

1. Design $c_{iss} = \ell C'_A = 1.5\text{pF}$

Design input stage noise performance: SLiCAP

Noise model:



Given:

$$\begin{cases} C'_A = 8.33 \times 10^{-12} \text{ [Fm}^{-1}\text{]} \\ \ell = 0.18 \text{ [m]} \end{cases}$$

Required:

$$\begin{cases} S_E = 25 \times 10^{-18} \text{ [V}^2\text{m}^{-2}\text{Hz}^{-1}\text{]} \\ f_\ell = 100 \times 10^3 \text{ [Hz]} \end{cases}$$

Determine I_{DS} , L , W based on spectrum noise floor and corner frequency 1/f noise

$$S_E = \frac{1}{\ell^2} \left(\frac{4kT\Gamma n}{g_m} \left(1 + \frac{c_{iss}}{\ell C'_A} \right)^2 + \frac{2KF}{3c_{iss}} \left(1 + \frac{c_{iss}}{\ell C'_A} \right)^2 \frac{1}{f} \right)$$

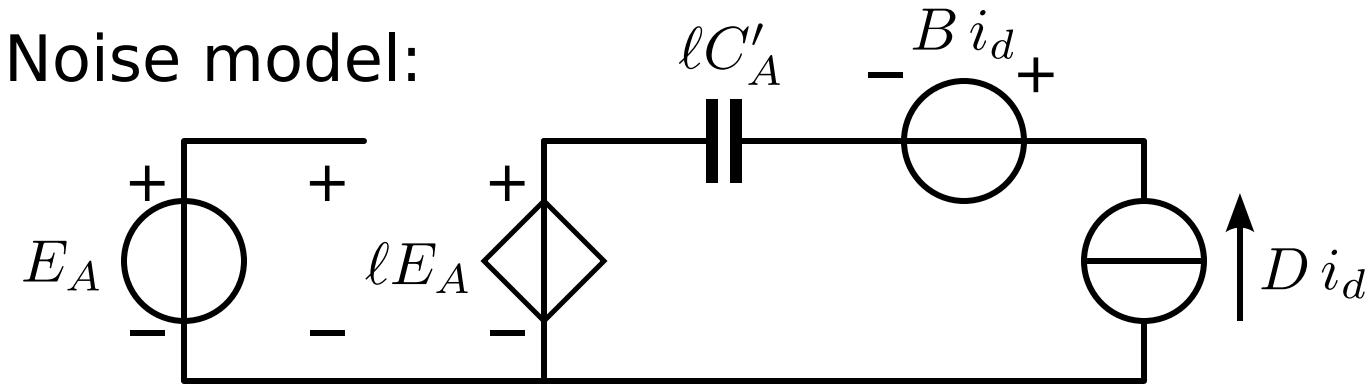
Lowest corner frequency 1/f noise if $c_{iss} = \ell C'_A$

Minimum length for given requirements and process: $\ell > 2 \sqrt[3]{\frac{KF}{3S_E C'_A f_\ell}}$

1. Design $c_{iss} = \ell C'_A = 1.5\text{pF}$ $WL \approx c_{iss} \frac{3}{2} \frac{t_{ox}}{\epsilon_0 \epsilon_{\text{SiO}_2}}$

Design input stage noise performance: SLiCAP

Noise model:



Given:

$$\begin{cases} C'_A = 8.33 \times 10^{-12} \text{ [Fm}^{-1}\text{]} \\ \ell = 0.18 \text{ [m]} \end{cases}$$

Required:

$$\begin{cases} S_E = 25 \times 10^{-18} \text{ [V}^2\text{m}^{-2}\text{Hz}^{-1}\text{]} \\ f_\ell = 100 \times 10^3 \text{ [Hz]} \end{cases}$$

Determine I_{DS} , L , W based on spectrum noise floor and corner frequency 1/f noise

$$S_E = \frac{1}{\ell^2} \left(\frac{4kT\Gamma n}{g_m} \left(1 + \frac{c_{iss}}{\ell C'_A} \right)^2 + \frac{2KF}{3c_{iss}} \left(1 + \frac{c_{iss}}{\ell C'_A} \right)^2 \frac{1}{f} \right)$$

Lowest corner frequency 1/f noise if $c_{iss} = \ell C'_A$

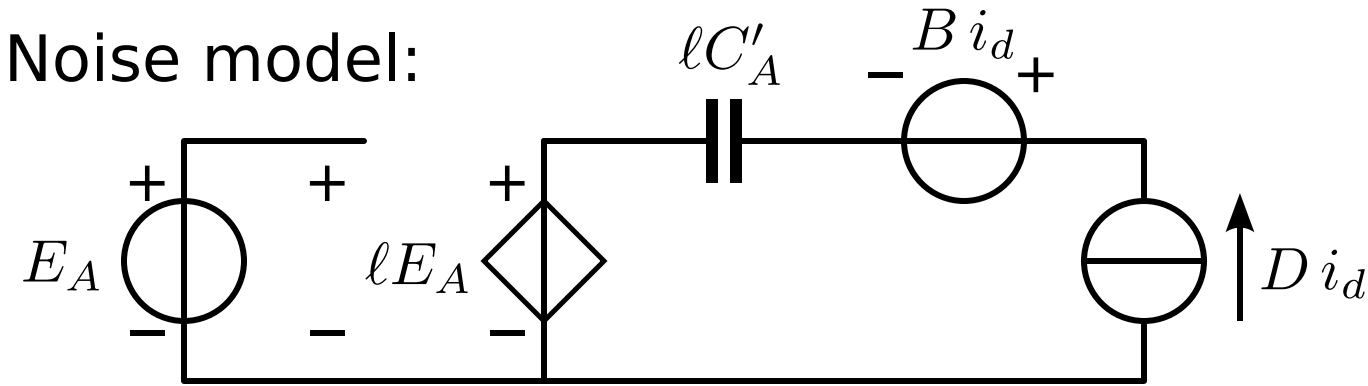
Minimum length for given requirements and process: $\ell > 2 \sqrt[3]{\frac{KF}{3S_E C'_A f_\ell}}$

$$1. \text{ Design } c_{iss} = \ell C'_A = 1.5 \text{ pF} \quad WL \approx c_{iss} \frac{3}{2} \frac{t_{ox}}{\epsilon_0 \epsilon_{\text{SiO}_2}}$$

2. Derive requirement floor noise

Design input stage noise performance: SLiCAP

Noise model:



Given:

$$\begin{cases} C'_A = 8.33 \times 10^{-12} \text{ [Fm}^{-1}\text{]} \\ \ell = 0.18 \text{ [m]} \end{cases}$$

Required:

$$\begin{cases} S_E = 25 \times 10^{-18} \text{ [V}^2\text{m}^{-2}\text{Hz}^{-1}\text{]} \\ f_\ell = 100 \times 10^3 \text{ [Hz]} \end{cases}$$

Determine I_{DS} , L , W based on spectrum noise floor and corner frequency 1/f noise

$$S_E = \frac{1}{\ell^2} \left(\frac{4kT\Gamma n}{g_m} \left(1 + \frac{c_{iss}}{\ell C'_A} \right)^2 + \frac{2KF}{3c_{iss}} \left(1 + \frac{c_{iss}}{\ell C'_A} \right)^2 \frac{1}{f} \right)$$

Lowest corner frequency 1/f noise if $c_{iss} = \ell C'_A$

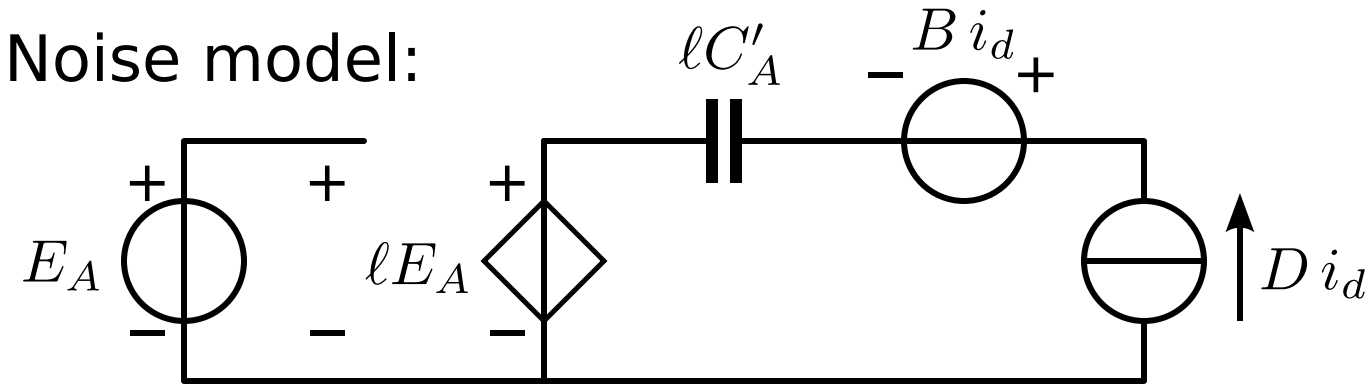
Minimum length for given requirements and process: $\ell > 2 \sqrt[3]{\frac{KF}{3S_E C'_A f_\ell}}$

$$1. \text{ Design } c_{iss} = \ell C'_A = 1.5\text{pF} \quad WL \approx c_{iss} \frac{3}{2} \frac{t_{ox}}{\epsilon_0 \epsilon_{\text{SiO}_2}}$$

$$2. \text{ Derive requirement floor noise } g_m = \frac{16kT\Gamma n}{\ell^2 S_E} = 58\text{mS}$$

Design input stage noise performance: SLiCAP

Noise model:



Given:

$$\begin{cases} C'_A = 8.33 \times 10^{-12} \text{ [Fm}^{-1}\text{]} \\ \ell = 0.18 \text{ [m]} \end{cases}$$

Required:

$$\begin{cases} S_E = 25 \times 10^{-18} \text{ [V}^2\text{m}^{-2}\text{Hz}^{-1}\text{]} \\ f_\ell = 100 \times 10^3 \text{ [Hz]} \end{cases}$$

Determine I_{DS} , L , W based on spectrum noise floor and corner frequency 1/f noise

$$S_E = \frac{1}{\ell^2} \left(\frac{4kT\Gamma n}{g_m} \left(1 + \frac{c_{iss}}{\ell C'_A} \right)^2 + \frac{2KF}{3c_{iss}} \left(1 + \frac{c_{iss}}{\ell C'_A} \right)^2 \frac{1}{f} \right)$$

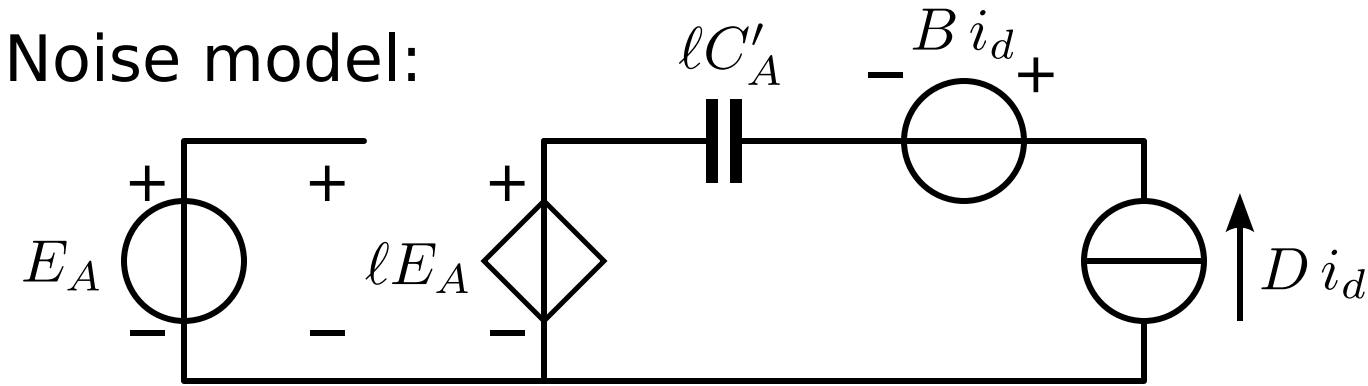
Lowest corner frequency 1/f noise if $c_{iss} = \ell C'_A$

Minimum length for given requirements and process: $\ell > 2 \sqrt[3]{\frac{KF}{3S_E C'_A f_\ell}}$

1. Design $c_{iss} = \ell C'_A = 1.5\text{pF}$ $WL \approx c_{iss} \frac{3}{2} \frac{t_{ox}}{\epsilon_0 \epsilon_{\text{SiO}_2}}$
2. Derive requirement floor noise $g_m = \frac{16kT\Gamma n}{\ell^2 S_E} = 58\text{mS}$
3. Calculate $f_T = \frac{g_m}{2\pi c_{iss}} = 6.2\text{GHz}$

Design input stage noise performance: SLiCAP

Noise model:



Given:

$$\begin{cases} C'_A = 8.33 \times 10^{-12} \text{ [Fm}^{-1}\text{]} \\ \ell = 0.18 \text{ [m]} \end{cases}$$

Required:

$$\begin{cases} S_E = 25 \times 10^{-18} \text{ [V}^2\text{m}^{-2}\text{Hz}^{-1}\text{]} \\ f_\ell = 100 \times 10^3 \text{ [Hz]} \end{cases}$$

Determine I_{DS} , L , W based on spectrum noise floor and corner frequency 1/f noise

$$S_E = \frac{1}{\ell^2} \left(\frac{4kT\Gamma n}{g_m} \left(1 + \frac{c_{iss}}{\ell C'_A} \right)^2 + \frac{2KF}{3c_{iss}} \left(1 + \frac{c_{iss}}{\ell C'_A} \right)^2 \frac{1}{f} \right)$$

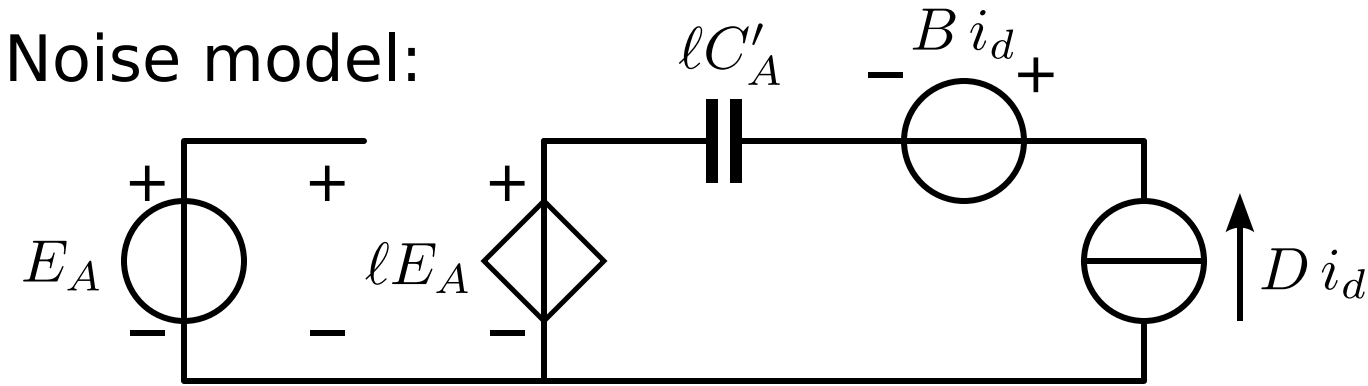
Lowest corner frequency 1/f noise if $c_{iss} = \ell C'_A$

Minimum length for given requirements and process: $\ell > 2 \sqrt[3]{\frac{KF}{3S_E C'_A f_\ell}}$

1. Design $c_{iss} = \ell C'_A = 1.5\text{pF}$ $WL \approx c_{iss} \frac{3}{2} \frac{t_{ox}}{\epsilon_0 \epsilon_{\text{SiO}_2}}$
2. Derive requirement floor noise $g_m = \frac{16kT\Gamma n}{\ell^2 S_E} = 58\text{mS}$
3. Calculate $f_T = \frac{g_m}{2\pi c_{iss}} = 6.2\text{GHz}$
4. Check $f_\ell = KF \frac{\pi}{3kTn\Gamma} f_T \approx 10^{-4} f_T = 620\text{kHz}$

Design input stage noise performance: SLiCAP

Noise model:



Given:

$$\begin{cases} C'_A = 8.33 \times 10^{-12} \text{ [Fm}^{-1}\text{]} \\ \ell = 0.18 \text{ [m]} \end{cases}$$

Required:

$$\begin{cases} S_E = 25 \times 10^{-18} \text{ [V}^2\text{m}^{-2}\text{Hz}^{-1}\text{]} \\ f_\ell = 100 \times 10^3 \text{ [Hz]} \end{cases}$$

Determine I_{DS} , L , W based on spectrum noise floor and corner frequency 1/f noise

$$S_E = \frac{1}{\ell^2} \left(\frac{4kT\Gamma n}{g_m} \left(1 + \frac{c_{iss}}{\ell C'_A} \right)^2 + \frac{2KF}{3c_{iss}} \left(1 + \frac{c_{iss}}{\ell C'_A} \right)^2 \frac{1}{f} \right)$$

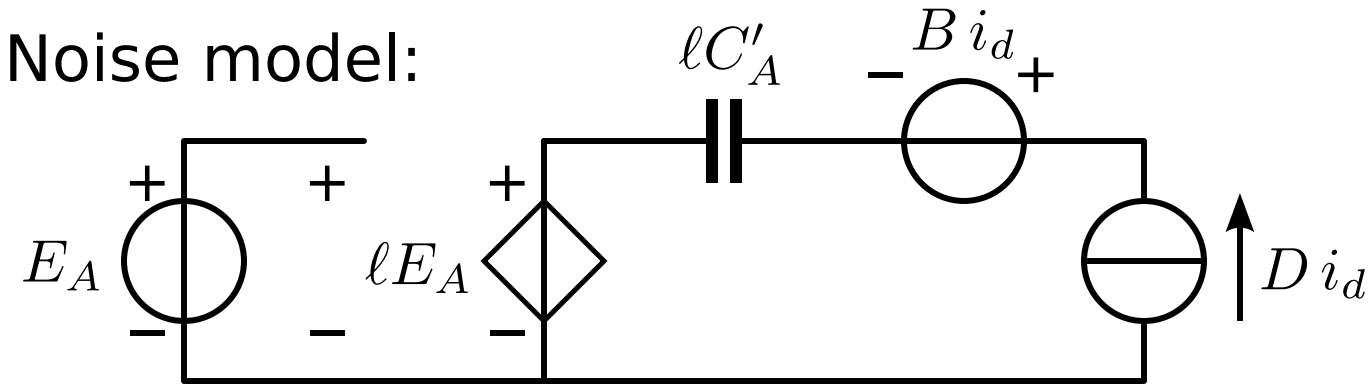
Lowest corner frequency 1/f noise if $c_{iss} = \ell C'_A$

Minimum length for given requirements and process: $\ell > 2 \sqrt[3]{\frac{KF}{3S_E C'_A f_\ell}}$

1. Design $c_{iss} = \ell C'_A = 1.5\text{pF}$ $WL \approx c_{iss} \frac{3}{2} \frac{t_{ox}}{\epsilon_0 \epsilon_{\text{SiO}_2}}$
2. Derive requirement floor noise $g_m = \frac{16kT\Gamma n}{\ell^2 S_E} = 58\text{mS}$
3. Calculate $f_T = \frac{g_m}{2\pi c_{iss}} = 6.2\text{GHz}$
4. Check $f_\ell = KF \frac{\pi}{3kTn\Gamma} f_T \approx 10^{-4} f_T = 620\text{kHz}$ **show stopper!**

Design input stage noise performance: SLiCAP

Noise model:



Given:

$$\begin{cases} C'_A = 8.33 \times 10^{-12} \text{ [Fm}^{-1}\text{]} \\ \ell = 0.18 \text{ [m]} \end{cases}$$

Required:

$$\begin{cases} S_E = 25 \times 10^{-18} \text{ [V}^2\text{m}^{-2}\text{Hz}^{-1}\text{]} \\ f_\ell = 100 \times 10^3 \text{ [Hz]} \end{cases}$$

Determine I_{DS} , L , W based on spectrum noise floor and corner frequency 1/f noise

$$S_E = \frac{1}{\ell^2} \left(\frac{4kT\Gamma n}{g_m} \left(1 + \frac{c_{iss}}{\ell C'_A} \right)^2 + \frac{2KF}{3c_{iss}} \left(1 + \frac{c_{iss}}{\ell C'_A} \right)^2 \frac{1}{f} \right)$$

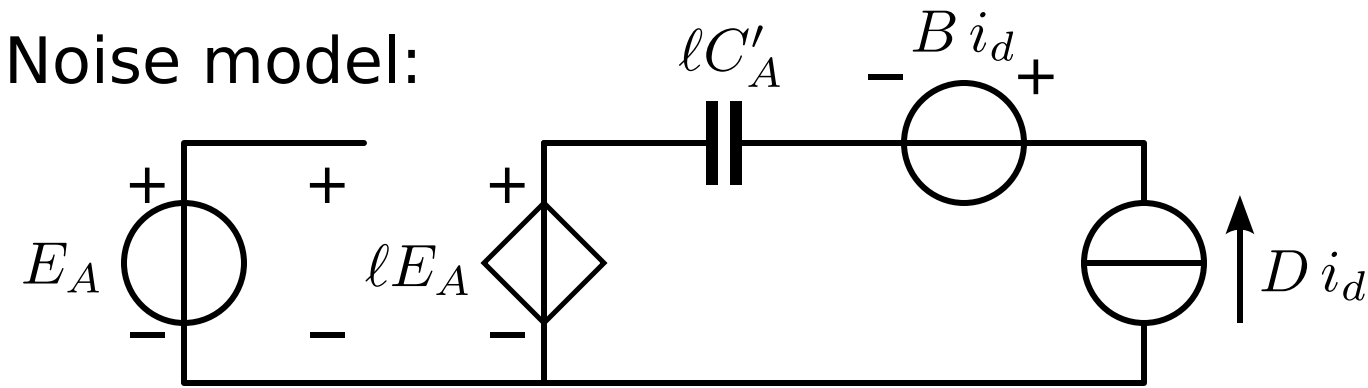
Lowest corner frequency 1/f noise if $c_{iss} = \ell C'_A$

Minimum length for given requirements and process: $\ell > 2 \sqrt[3]{\frac{KF}{3S_E C'_A f_\ell}}$

1. Design $c_{iss} = \ell C'_A = 1.5\text{pF}$ $WL \approx c_{iss} \frac{3}{2} \frac{t_{ox}}{\epsilon_0 \epsilon_{\text{SiO}_2}}$
2. Derive requirement floor noise $g_m = \frac{16kT\Gamma n}{\ell^2 S_E} = 58\text{mS}$
3. Calculate $f_T = \frac{g_m}{2\pi c_{iss}} = 6.2\text{GHz}$
4. Check $f_\ell = KF \frac{\pi}{3kTn\Gamma} f_T \approx 10^{-4} f_T = 620\text{kHz}$ **show stopper!**
5. If possible adjust drain current to obtain the correct noise floor:

Design input stage noise performance: SLiCAP

Noise model:



Given:

$$\begin{cases} C'_A = 8.33 \times 10^{-12} \text{ [Fm}^{-1}\text{]} \\ \ell = 0.18 \text{ [m]} \end{cases}$$

Required:

$$\begin{cases} S_E = 25 \times 10^{-18} \text{ [V}^2\text{m}^{-2}\text{Hz}^{-1}\text{]} \\ f_\ell = 100 \times 10^3 \text{ [Hz]} \end{cases}$$

Determine I_{DS} , L , W based on spectrum noise floor and corner frequency 1/f noise

$$S_E = \frac{1}{\ell^2} \left(\frac{4kT\Gamma n}{g_m} \left(1 + \frac{c_{iss}}{\ell C'_A} \right)^2 + \frac{2KF}{3c_{iss}} \left(1 + \frac{c_{iss}}{\ell C'_A} \right)^2 \frac{1}{f} \right)$$

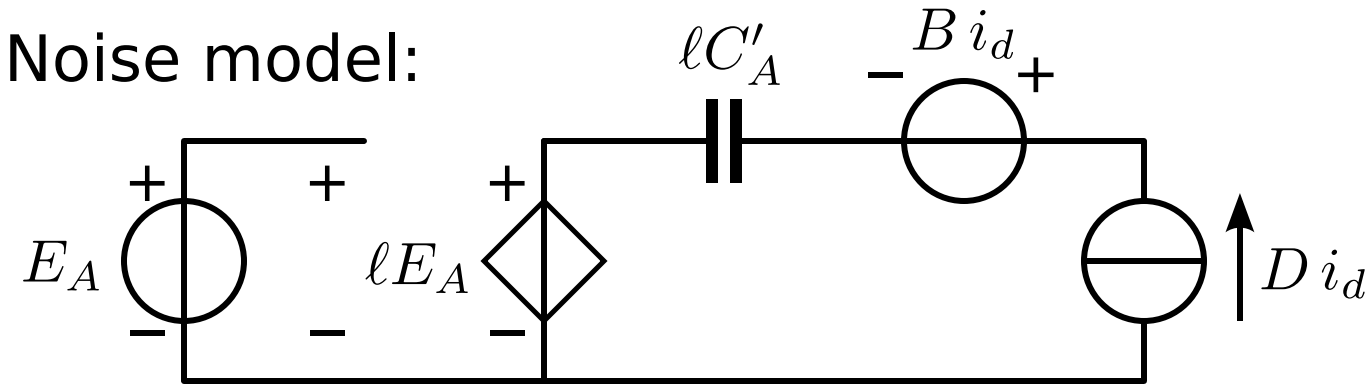
Lowest corner frequency 1/f noise if $c_{iss} = \ell C'_A$

Minimum length for given requirements and process: $\ell > 2 \sqrt[3]{\frac{KF}{3S_E C'_A f_\ell}}$

1. Design $c_{iss} = \ell C'_A = 1.5\text{pF}$ $WL \approx c_{iss} \frac{3}{2} \frac{t_{ox}}{\epsilon_0 \epsilon_{\text{SiO}_2}}$
2. Derive requirement floor noise $g_m = \frac{16kT\Gamma n}{\ell^2 S_E} = 58\text{mS}$
3. Calculate $f_T = \frac{g_m}{2\pi c_{iss}} = 6.2\text{GHz}$
4. Check $f_\ell = KF \frac{\pi}{3kTn\Gamma} f_T \approx 10^{-4} f_T = 620\text{kHz}$ **show stopper!**
5. If possible adjust drain current to obtain the correct noise floor:
lowest current with shortest channel

Design input stage noise performance: SLiCAP

Noise model:



Given:

$$\begin{cases} C'_A = 8.33 \times 10^{-12} \text{ [Fm}^{-1}\text{]} \\ \ell = 0.18 \text{ [m]} \end{cases}$$

Required:

$$\begin{cases} S_E = 25 \times 10^{-18} \text{ [V}^2\text{m}^{-2}\text{Hz}^{-1}\text{]} \\ f_\ell = 100 \times 10^3 \text{ [Hz]} \end{cases}$$

Determine I_{DS} , L , W based on spectrum noise floor and corner frequency 1/f noise

$$S_E = \frac{1}{\ell^2} \left(\frac{4kT\Gamma n}{g_m} \left(1 + \frac{c_{iss}}{\ell C'_A} \right)^2 + \frac{2KF}{3c_{iss}} \left(1 + \frac{c_{iss}}{\ell C'_A} \right)^2 \frac{1}{f} \right)$$

Lowest corner frequency 1/f noise if $c_{iss} = \ell C'_A$

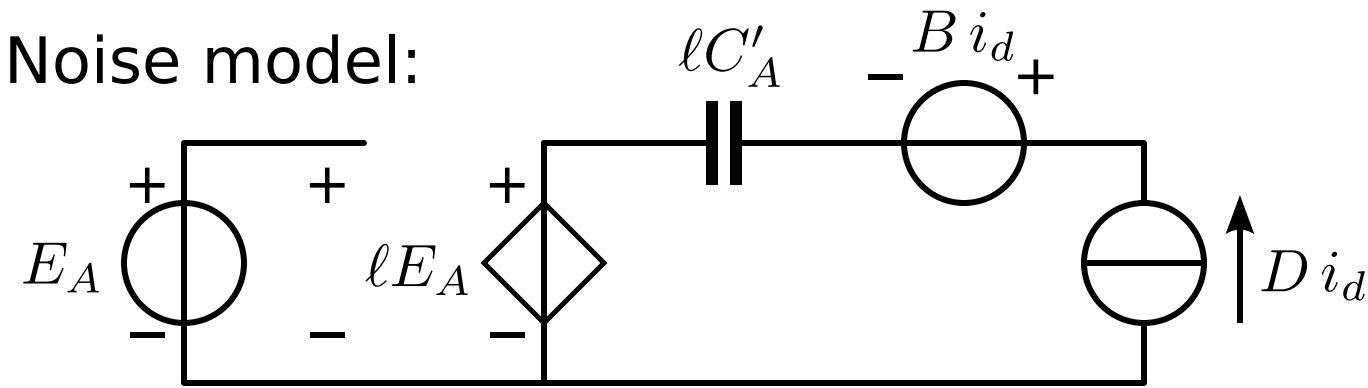
Minimum length for given requirements and process: $\ell > 2 \sqrt[3]{\frac{KF}{3S_E C'_A f_\ell}}$

1. Design $c_{iss} = \ell C'_A = 1.5\text{pF}$ $WL \approx c_{iss} \frac{3}{2} \frac{t_{ox}}{\epsilon_0 \epsilon_{\text{SiO}_2}}$
2. Derive requirement floor noise $g_m = \frac{16kT\Gamma n}{\ell^2 S_E} = 58\text{mS}$
3. Calculate $f_T = \frac{g_m}{2\pi c_{iss}} = 6.2\text{GHz}$
4. Check $f_\ell = KF \frac{\pi}{3kTn\Gamma} f_T \approx 10^{-4} f_T = 620\text{kHz}$ **show stopper!**
5. If possible adjust drain current to obtain the correct noise floor:
lowest current with shortest channel

Can be automated
using SLiCAP!

Design input stage noise performance: SLiCAP

Noise model:



Given:

$$\begin{cases} C'_A = 8.33 \times 10^{-12} \text{ [Fm}^{-1}\text{]} \\ \ell = 0.18 \text{ [m]} \end{cases}$$

Required:

$$\begin{cases} S_E = 25 \times 10^{-18} \text{ [V}^2\text{m}^{-2}\text{Hz}^{-1}\text{]} \\ f_\ell = 100 \times 10^3 \text{ [Hz]} \end{cases}$$

Determine I_{DS} , L , W based on spectrum noise floor and corner frequency 1/f noise

$$S_E = \frac{1}{\ell^2} \left(\frac{4kT\Gamma n}{g_m} \left(1 + \frac{c_{iss}}{\ell C'_A} \right)^2 + \frac{2KF}{3c_{iss}} \left(1 + \frac{c_{iss}}{\ell C'_A} \right)^2 \frac{1}{f} \right)$$

Lowest corner frequency 1/f noise if $c_{iss} = \ell C'_A$

Minimum length for given requirements and process: $\ell > 2 \sqrt[3]{\frac{KF}{3S_E C'_A f_\ell}}$

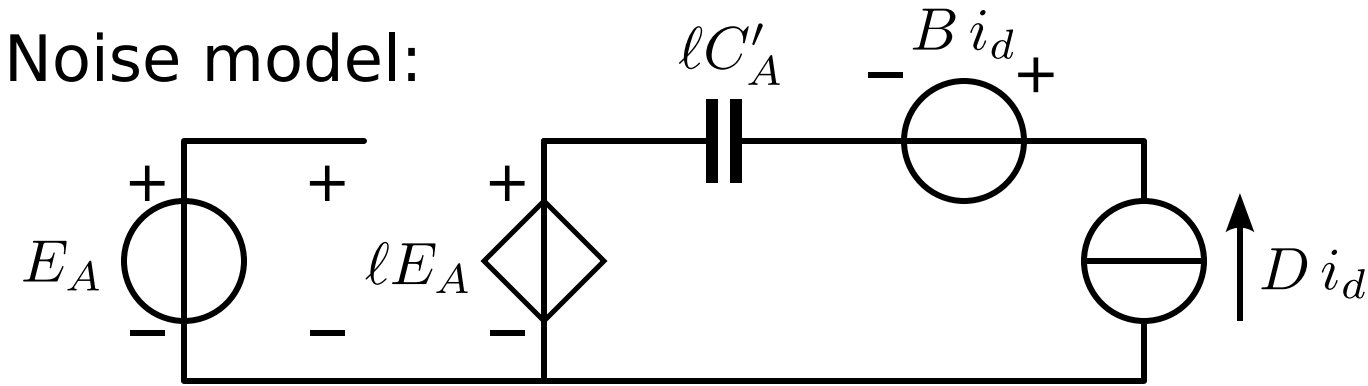
1. Design $c_{iss} = \ell C'_A = 1.5\text{pF}$ $WL \approx c_{iss} \frac{3}{2} \frac{t_{ox}}{\epsilon_0 \epsilon_{\text{SiO}_2}}$
2. Derive requirement floor noise $g_m = \frac{16kT\Gamma n}{\ell^2 S_E} = 58\text{mS}$
3. Calculate $f_T = \frac{g_m}{2\pi c_{iss}} = 6.2\text{GHz}$
4. Check $f_\ell = KF \frac{\pi}{3kTn\Gamma} f_T \approx 10^{-4} f_T = 620\text{kHz}$ **show stopper!**
5. If possible adjust drain current to obtain the correct noise floor:
lowest current with shortest channel

Can be automated
using SLiCAP!

[Demo](#)

Design input stage noise performance: SLiCAP

Noise model:



Given:

$$\begin{cases} C'_A = 8.33 \times 10^{-12} \text{ [Fm}^{-1}\text{]} \\ \ell = 0.18 \text{ [m]} \end{cases}$$

Required:

$$\begin{cases} S_E = 25 \times 10^{-18} \text{ [V}^2\text{m}^{-2}\text{Hz}^{-1}\text{]} \\ f_\ell = 100 \times 10^3 \text{ [Hz]} \end{cases}$$

Determine I_{DS} , L , W based on spectrum noise floor and corner frequency 1/f noise

$$S_E = \frac{1}{\ell^2} \left(\frac{4kT\Gamma n}{g_m} \left(1 + \frac{c_{iss}}{\ell C'_A} \right)^2 + \frac{2KF}{3c_{iss}} \left(1 + \frac{c_{iss}}{\ell C'_A} \right)^2 \frac{1}{f} \right)$$

Lowest corner frequency 1/f noise if $c_{iss} = \ell C'_A$

Minimum length for given requirements and process: $\ell > 2 \sqrt[3]{\frac{KF}{3S_E C'_A f_\ell}}$

1. Design $c_{iss} = \ell C'_A = 1.5\text{pF}$ $WL \approx c_{iss} \frac{3}{2} \frac{t_{ox}}{\epsilon_0 \epsilon_{\text{SiO}_2}}$
2. Derive requirement floor noise $g_m = \frac{16kT\Gamma n}{\ell^2 S_E} = 58\text{mS}$
3. Calculate $f_T = \frac{g_m}{2\pi c_{iss}} = 6.2\text{GHz}$
4. Check $f_\ell = KF \frac{\pi}{3kTn\Gamma} f_T \approx 10^{-4} f_T = 620\text{kHz}$ **show stopper!**
5. If possible adjust drain current to obtain the correct noise floor:
lowest current with shortest channel

Can be automated
using SLiCAP!

Demo

Structured Electronic Design

EE4109

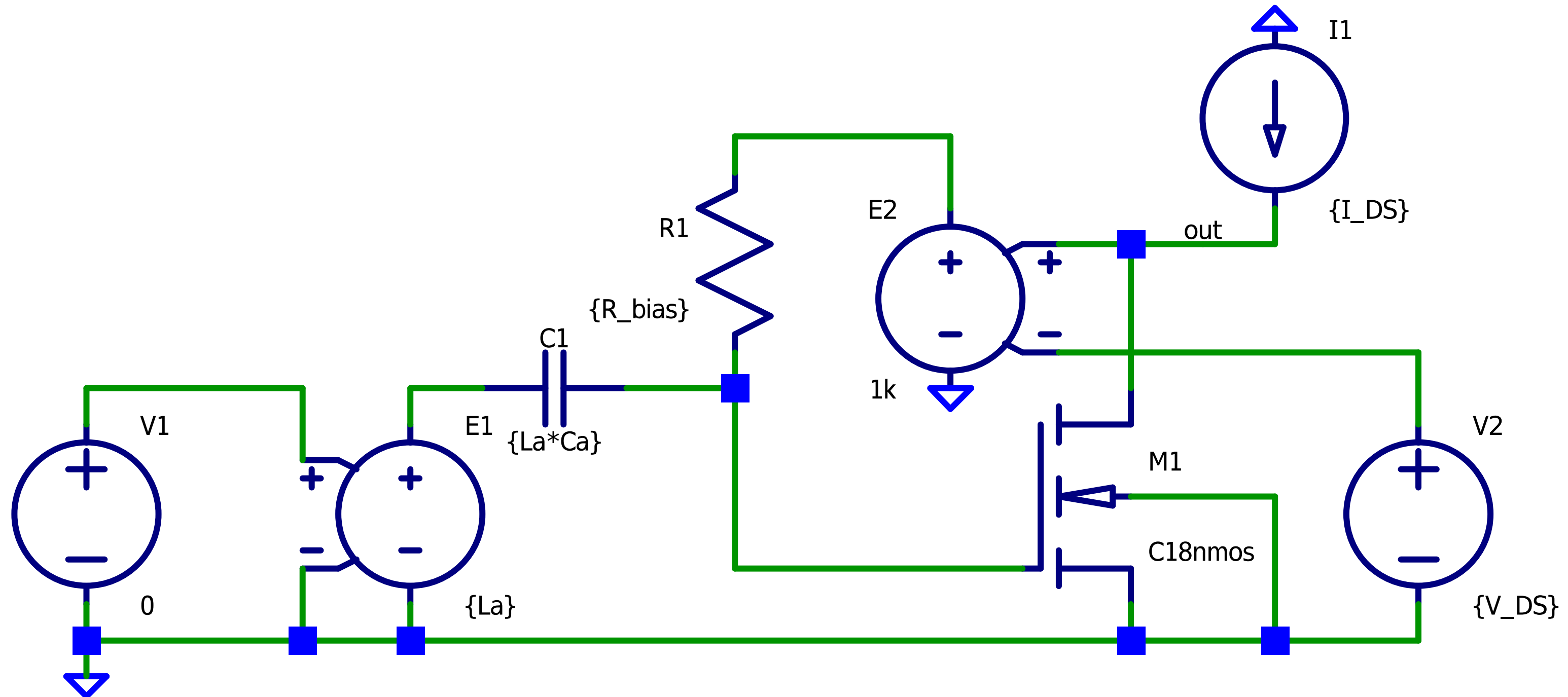
Homework 1

Design of a CS stage,
LTspice noise test bench

Anton J.M. Montagne

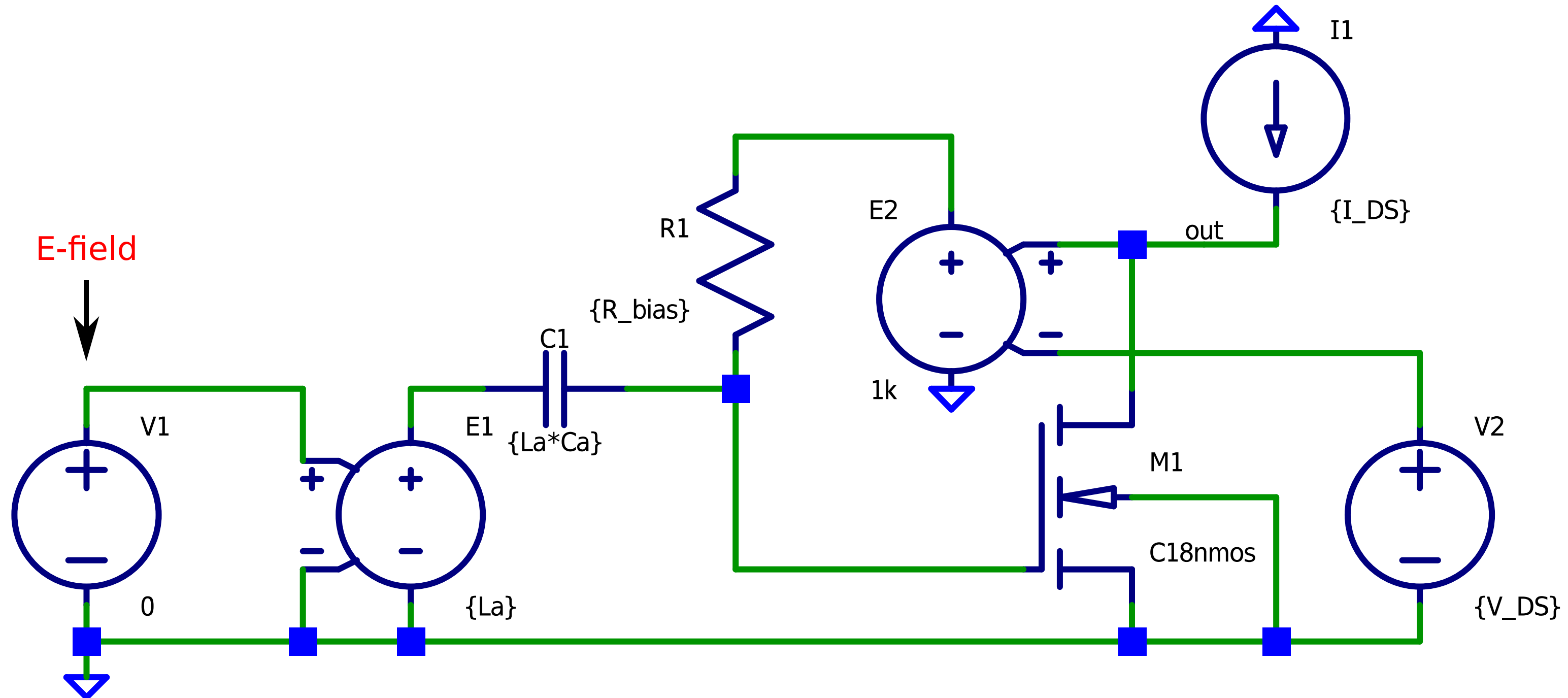
LTspice noise test bench

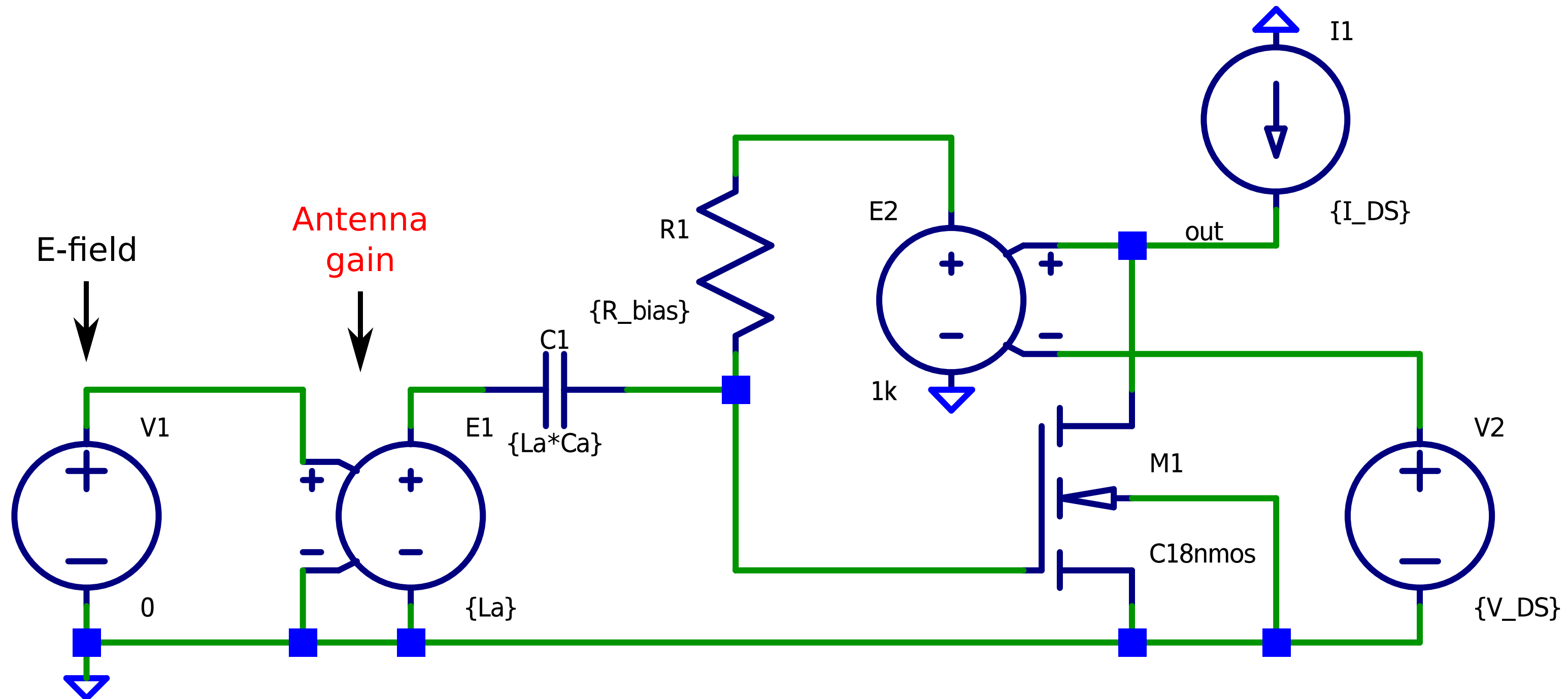
LTspice noise test bench



```
.param L=500n W=800u I_DS=1m V_DS=0.9 La=0.5 Ca=10p R_bias=1G  
.lib CMOS18TT.lib  
.noise V(out) V1 dec 20 1k 100meg
```

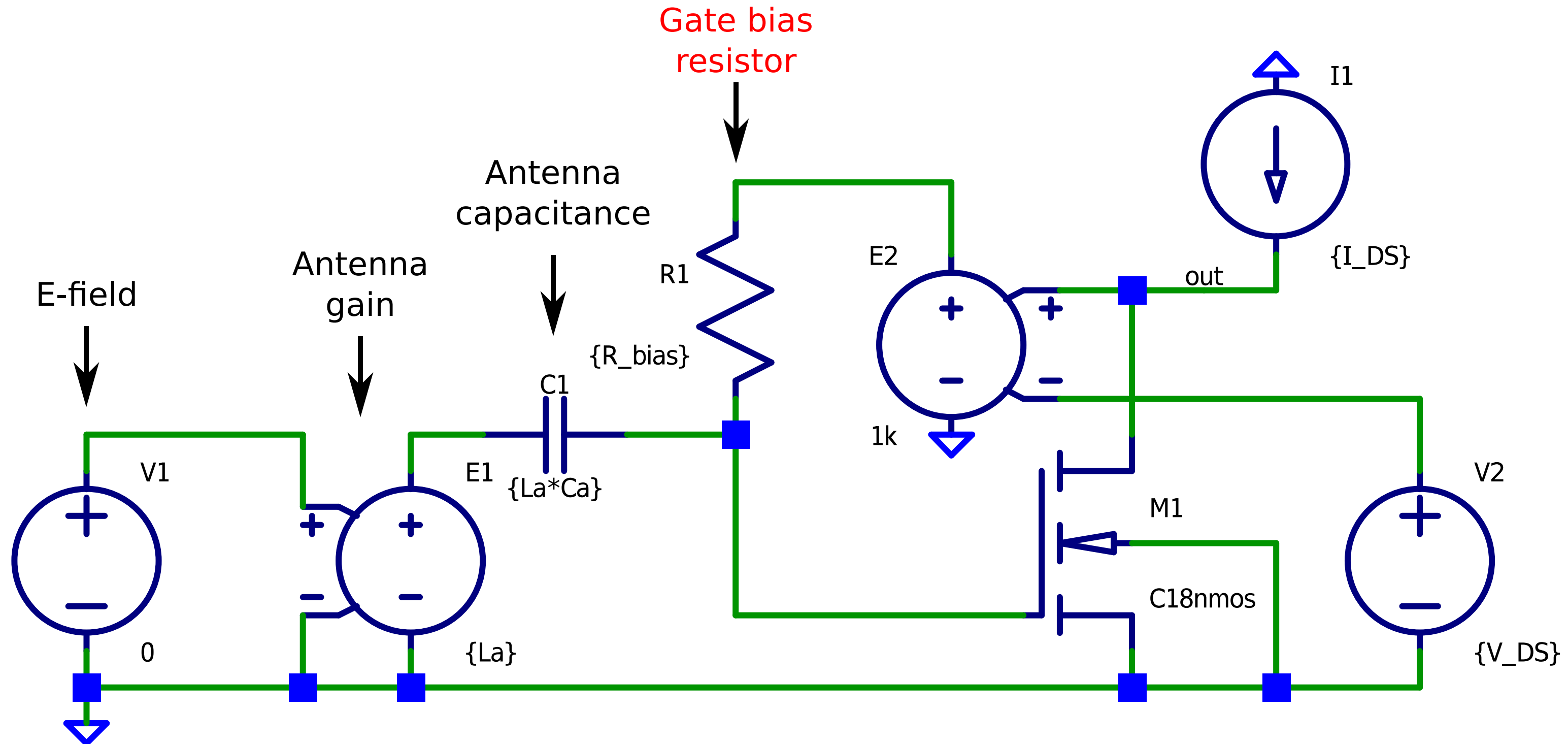
LTspice noise test bench





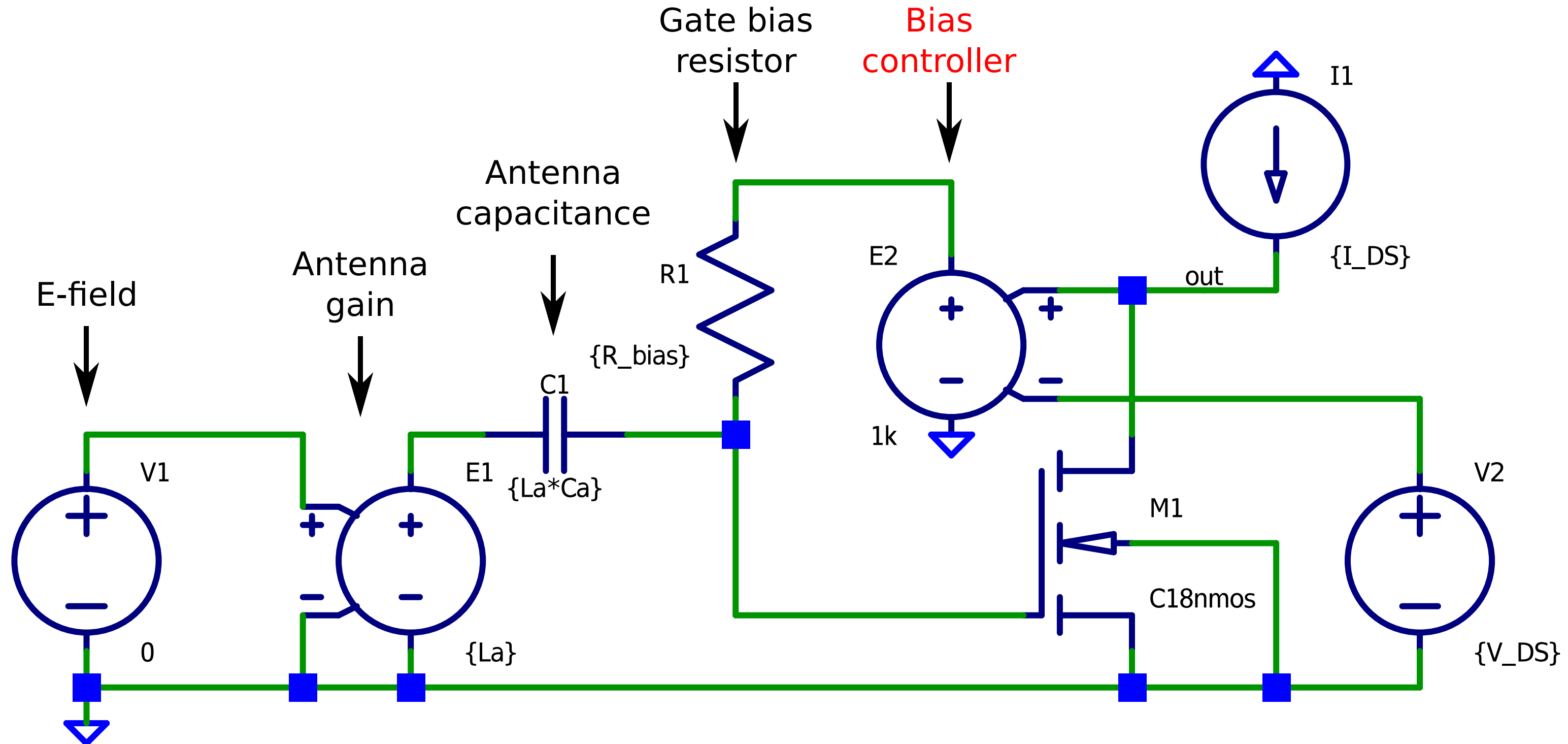
```
.param L=500n W=800u I_DS=1m V_DS=0.9 La=0.5 Ca=10p R_bias=1G
.lib CMOS18TT.lib
.noise V(out) V1 dec 20 1k 100meg
```

LTspice noise test bench

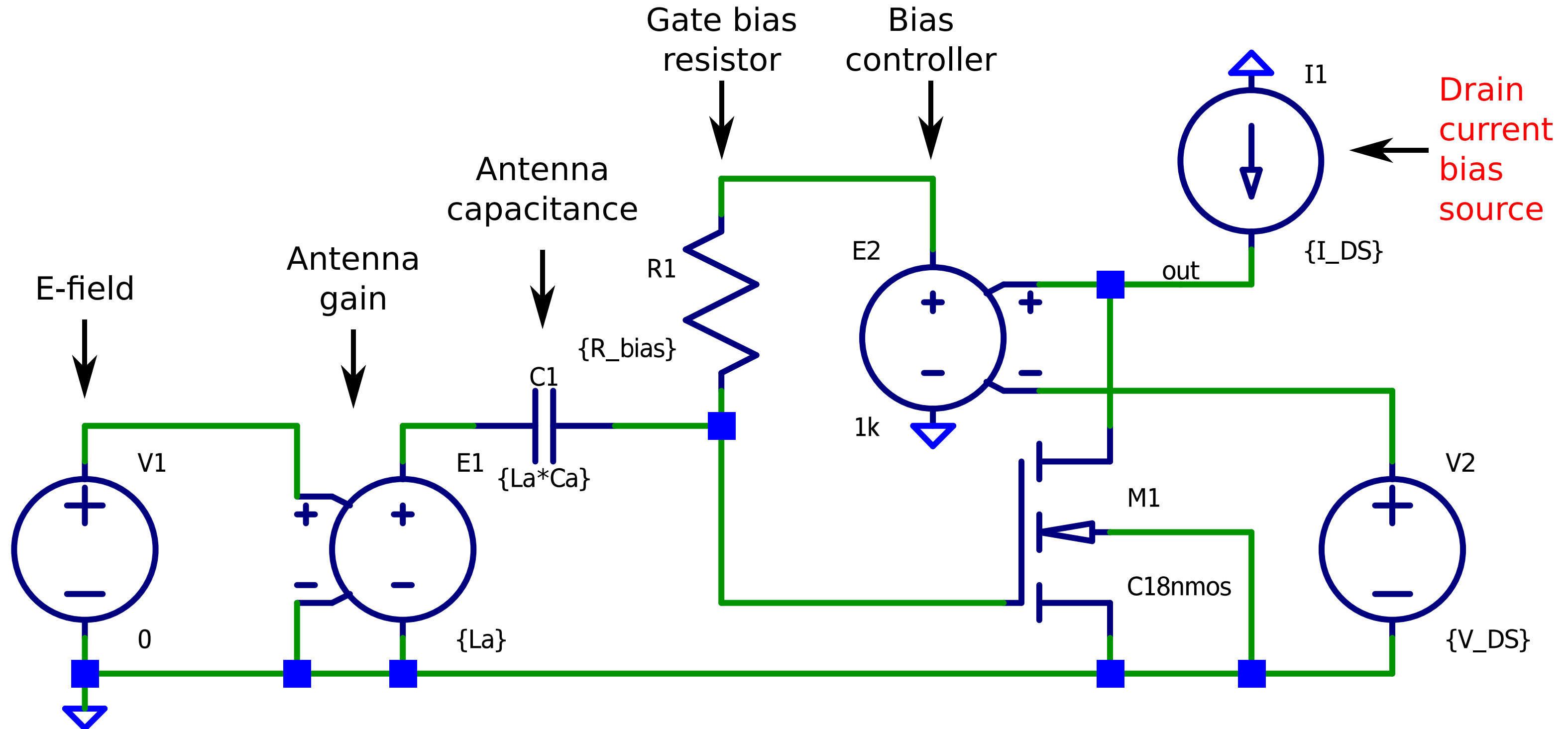


```
.param L=500n W=800u I_DS=1m V_DS=0.9 La=0.5 Ca=10p R_bias=1G
.lib CMOS18TT.lib
.noise V(out) V1 dec 20 1k 100meg
```

LTspice noise test bench

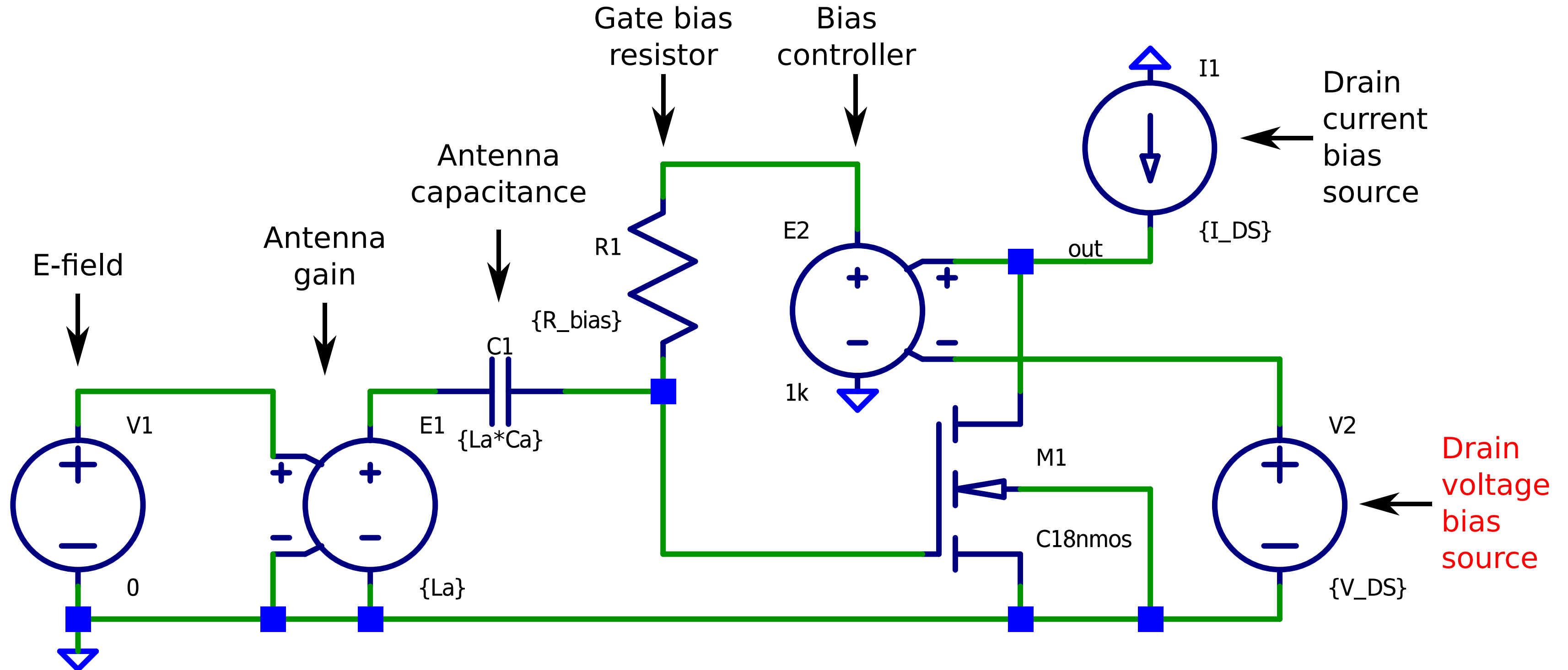


LTspice noise test bench



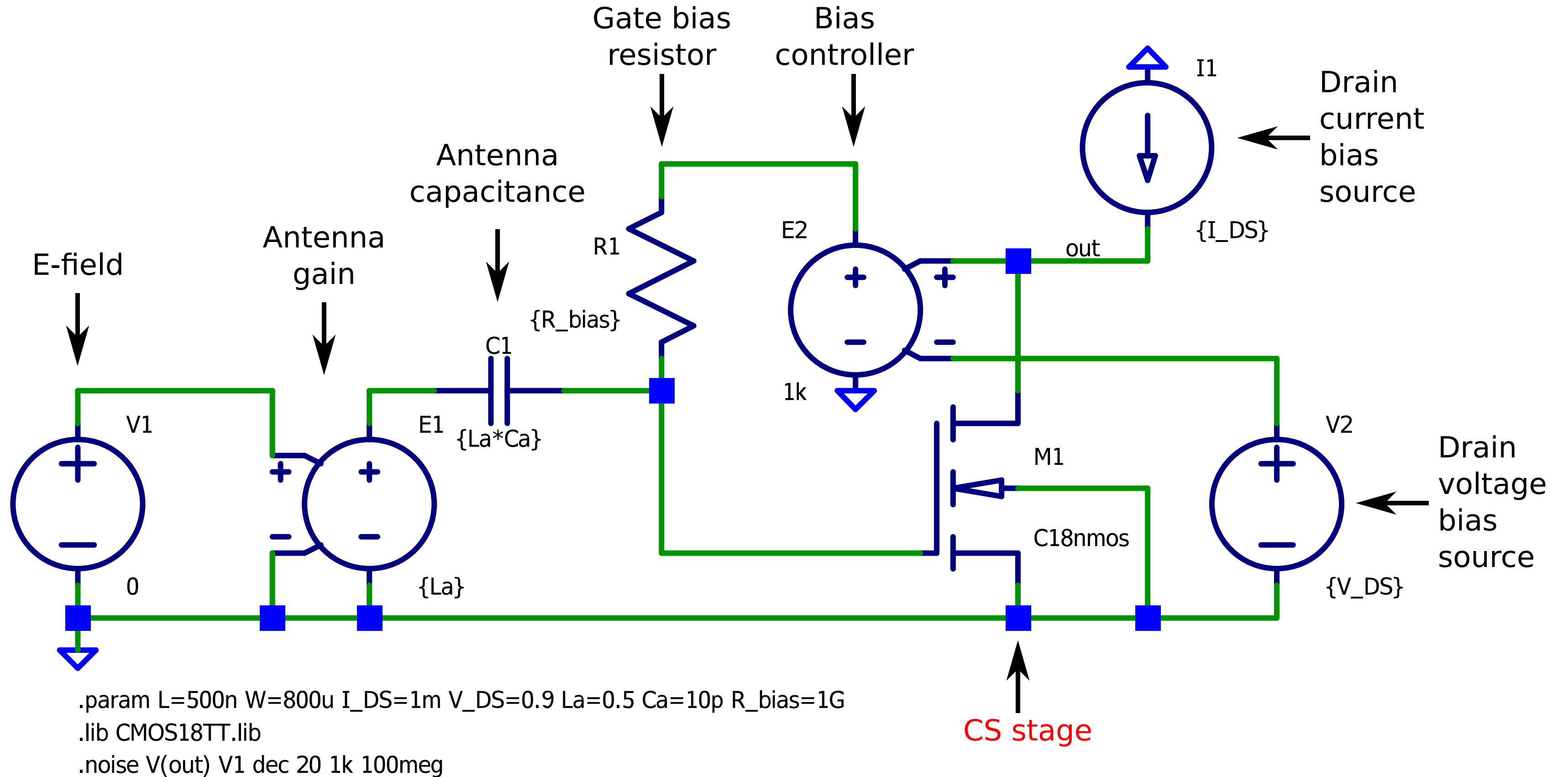
```
.param L=500n W=800u I_DS=1m V_DS=0.9 La=0.5 Ca=10p R_bias=1G
.lib CMOS18TT.lib
.noise V(out) V1 dec 20 1k 100meg
```

LTspice noise test bench

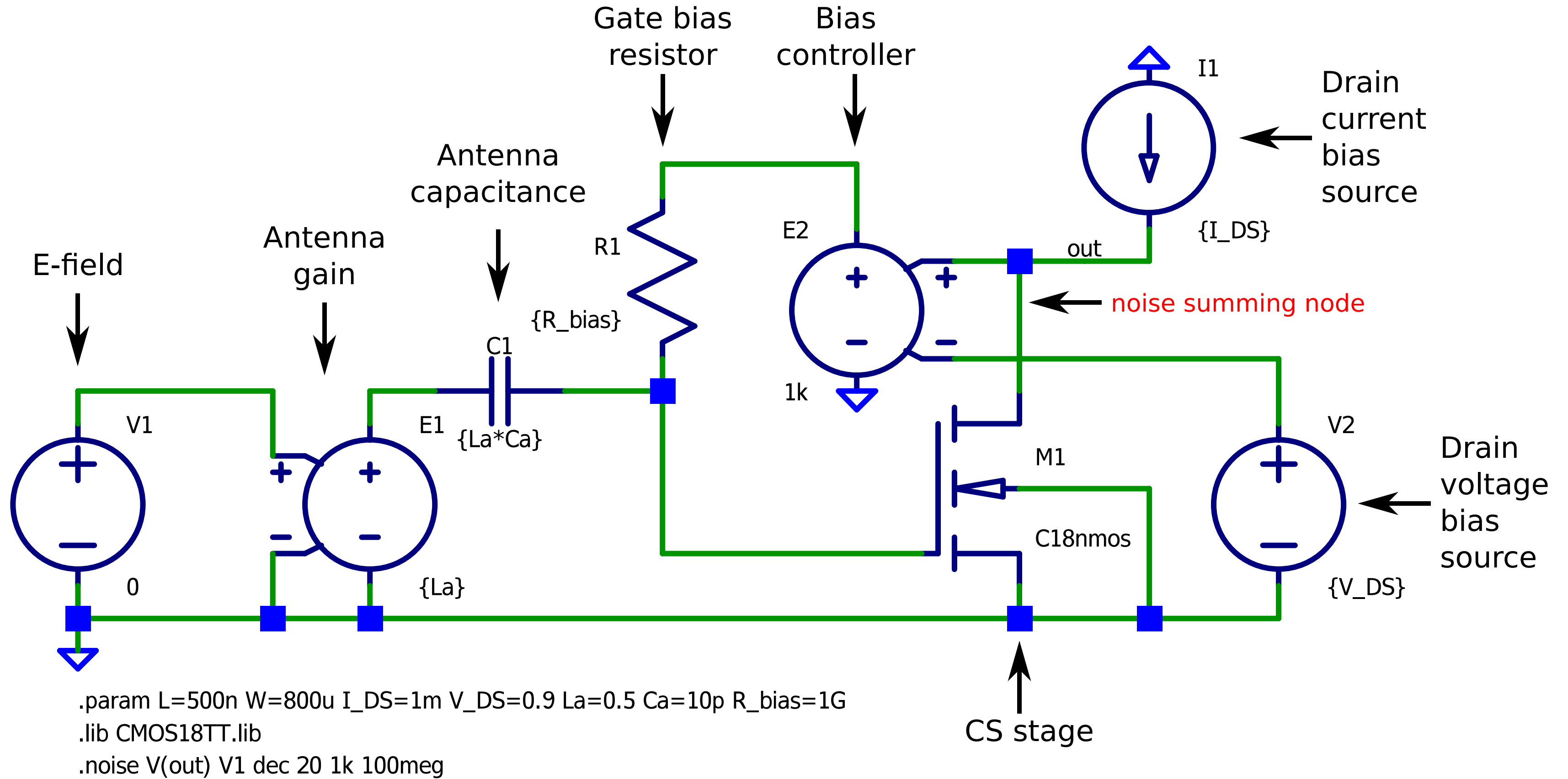


```
.param L=500n W=800u I_DS=1m V_DS=0.9 La=0.5 Ca=10p R_bias=1G
.lib CMOS18TT.lib
.noise V(out) V1 dec 20 1k 100meg
```

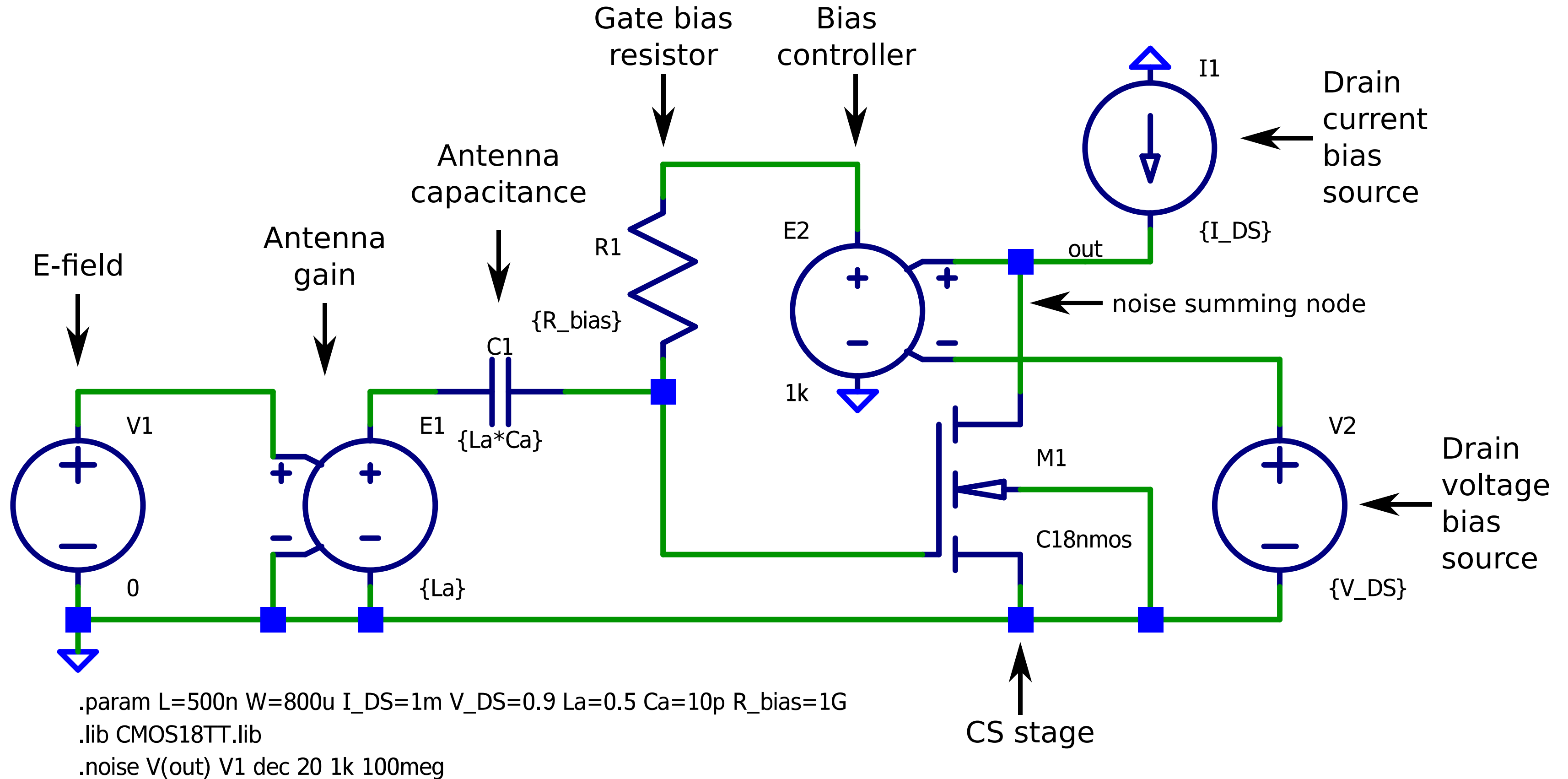
LTspice noise test bench



LTspice noise test bench

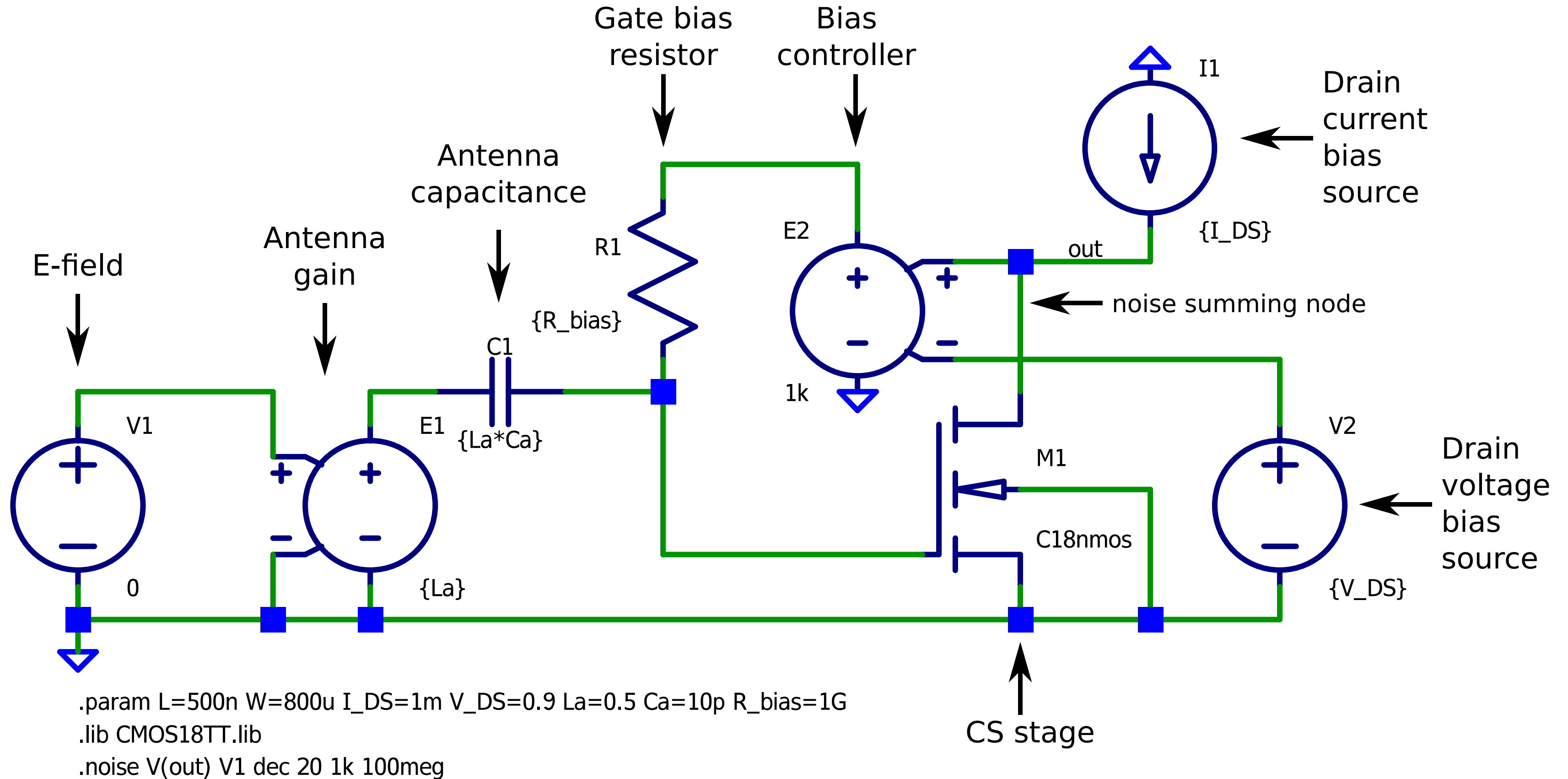


LTspice noise test bench



Always check for correct operating point!

LTspice noise test bench



Always check for correct operating point!

Structured Electronic Design

EE4109

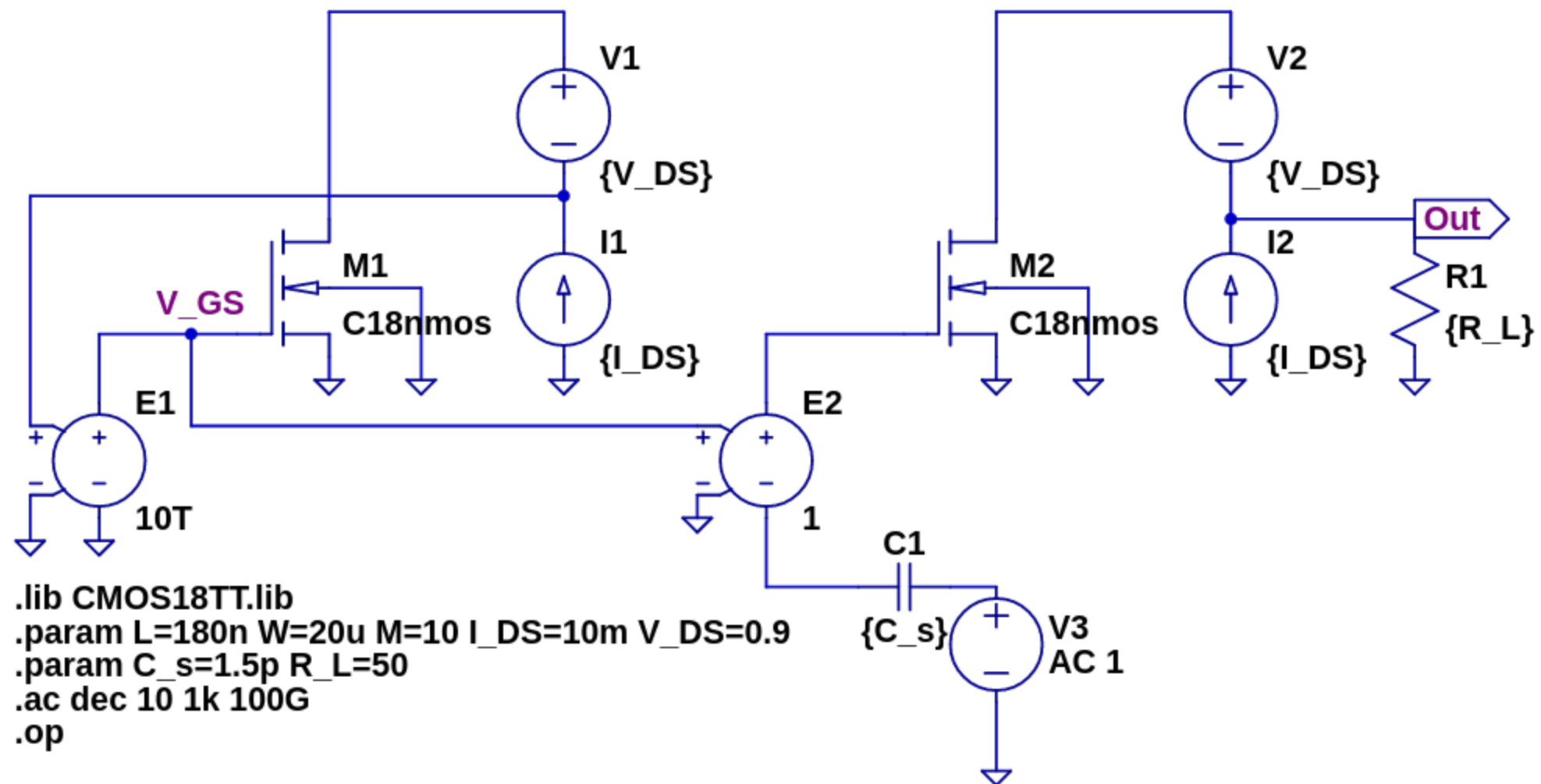
Homework 1

Design of a CS stage,
Homework remarks

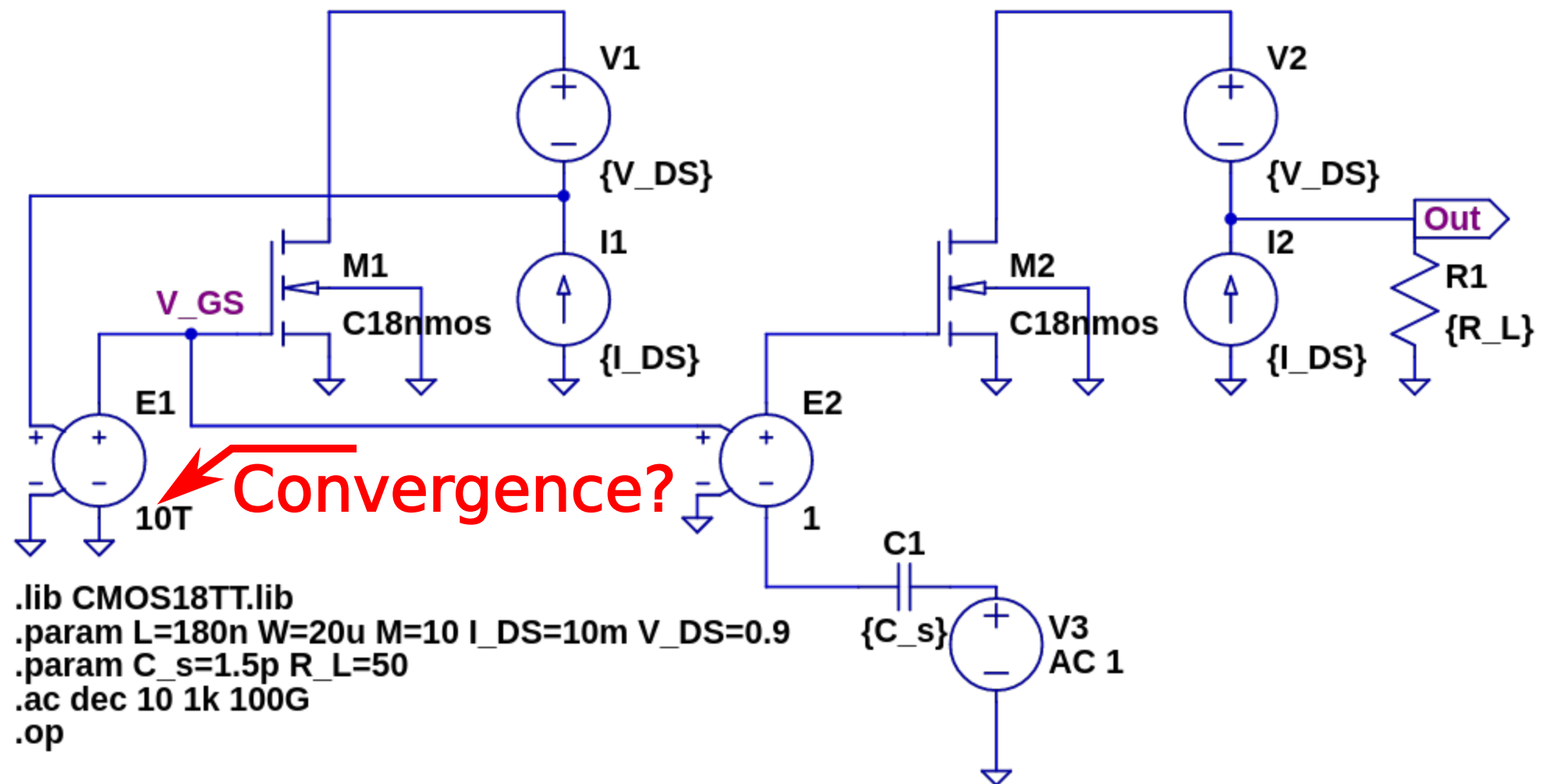
Anton J.M. Montagne

Bias error

Bias error



Bias error



Bias error

